



A DM Interpretation of Multiple Direct Detection Excesses

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+ Noah Kurinsky, Dan Baxter, Yonatan Kahn

[arXiv:2002.06937](https://arxiv.org/abs/2002.06937) *Phys. Rev. D* 102, 015017

Lund University Seminar Sep 24, 2020

Open Questions in Fundamental Physics

Neutrino Masses
Matter Asymmetry
Inflation



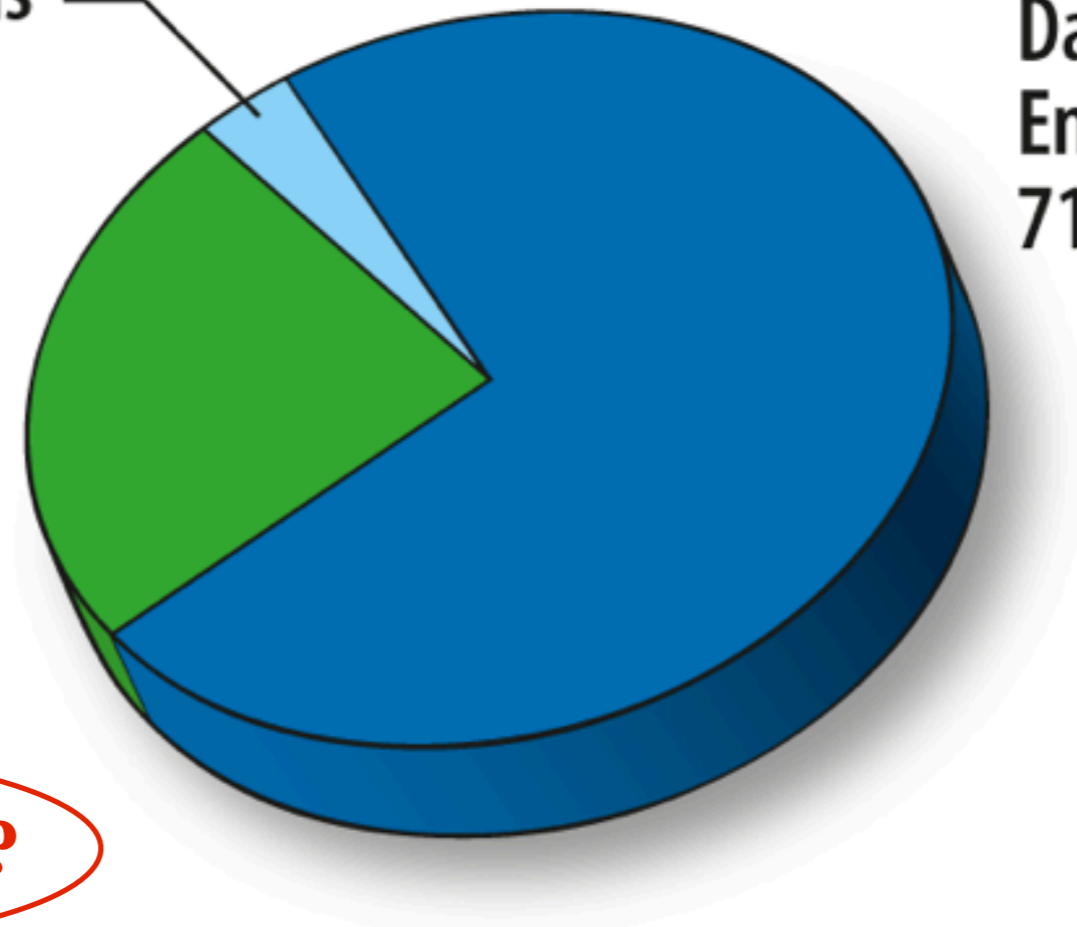
**Accelerated
Cosmic
Expansion**



Atoms
4.6%

Dark
Matter
24%

Dark
Energy
71.4%

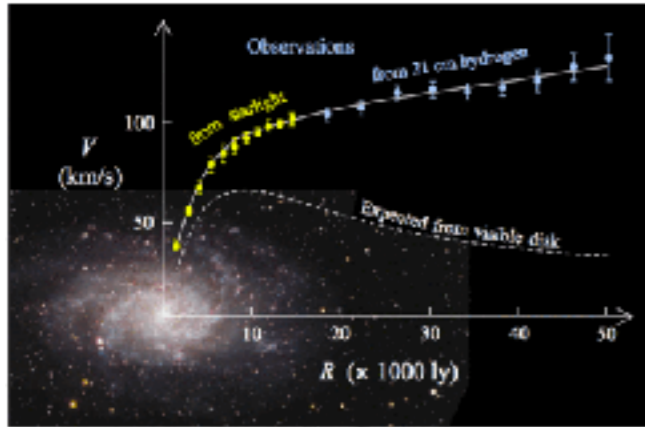


TODAY

What is this stuff?

Also Quantum Gravity

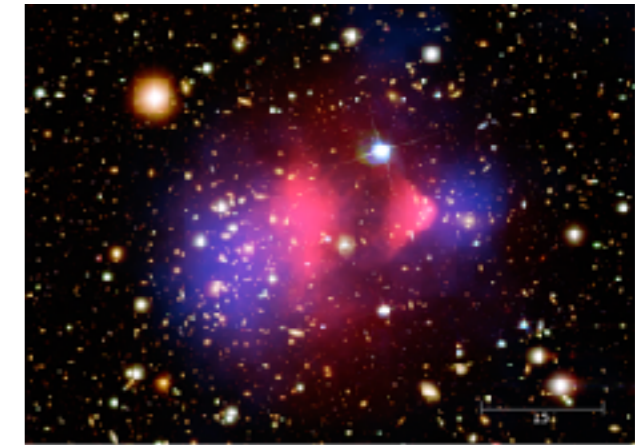
Remarkable Evidence for Dark Matter



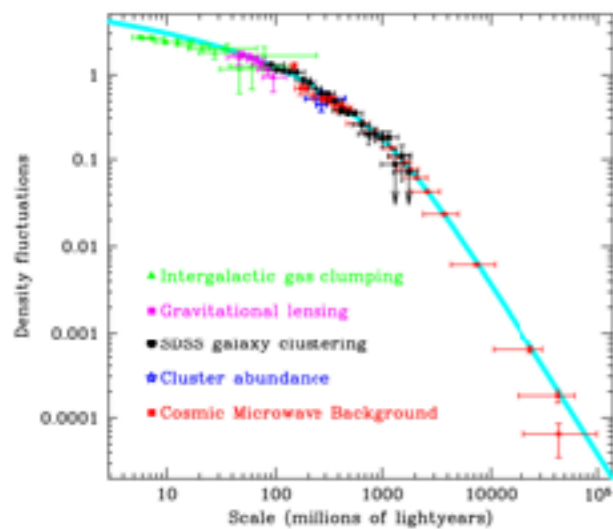
Rotation Curves



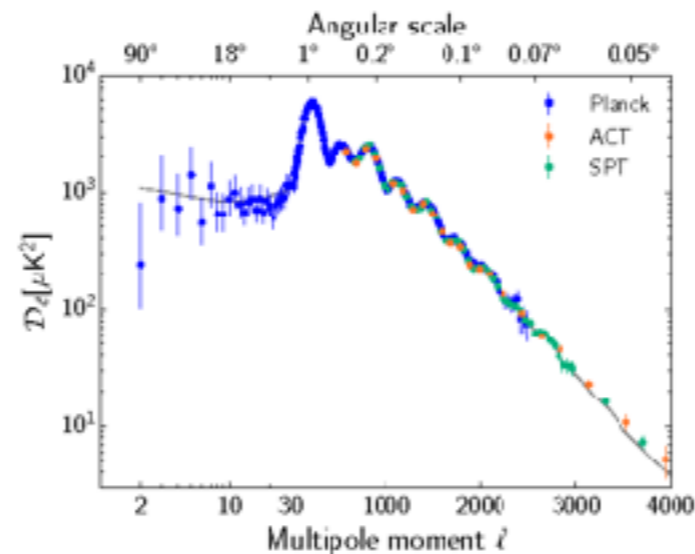
Gravitational Lensing



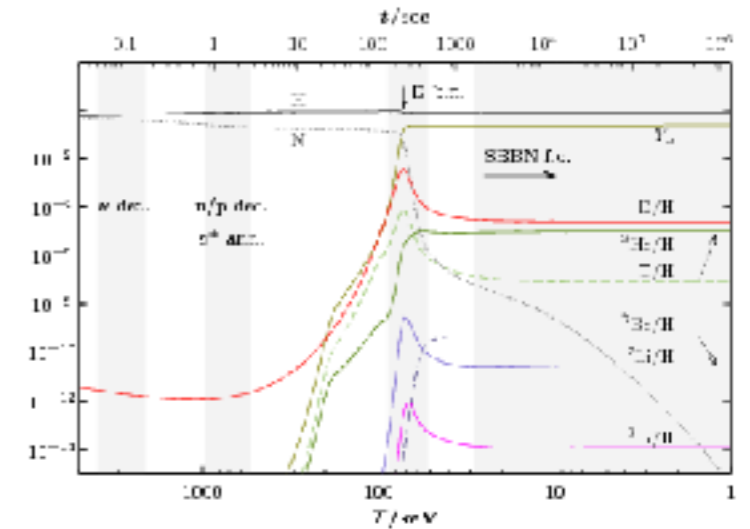
Cluster Collisions



Matter Power Spectrum



CMB Power Spectrum

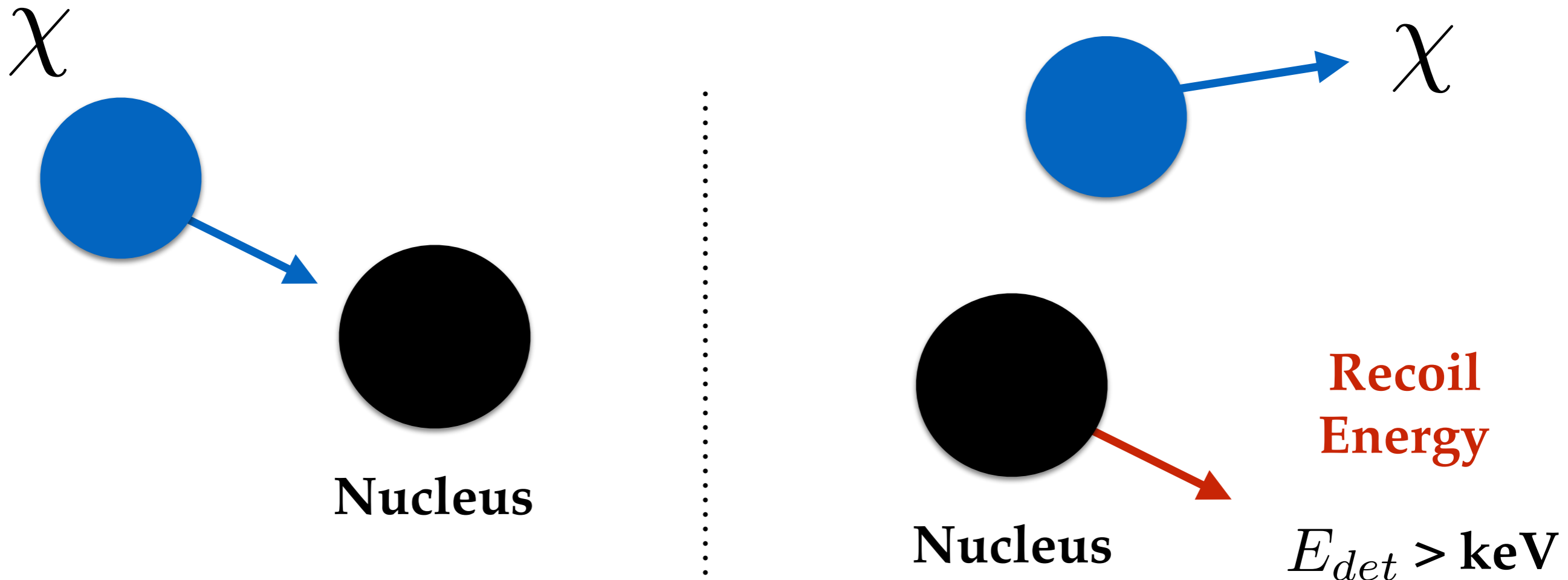


BBN Light Element Yields

Multiple independent, consistent observations
over **nearly** all of spacetime (!)

Holy Grail: extend our knowledge down to laboratory scales

Nuclear Recoil (NR) Direct Detection

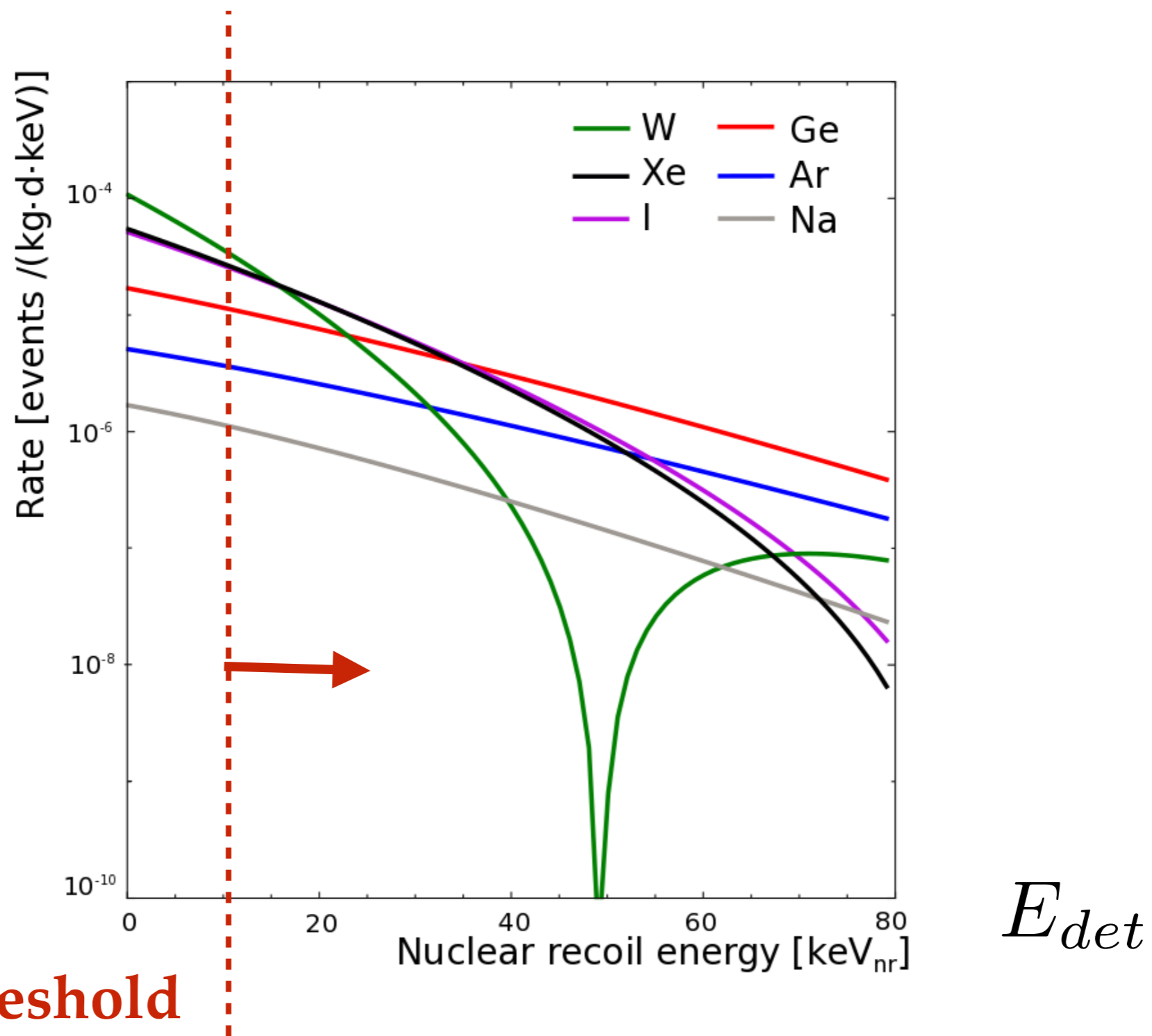


$$|\vec{q}| \sim \mu v$$

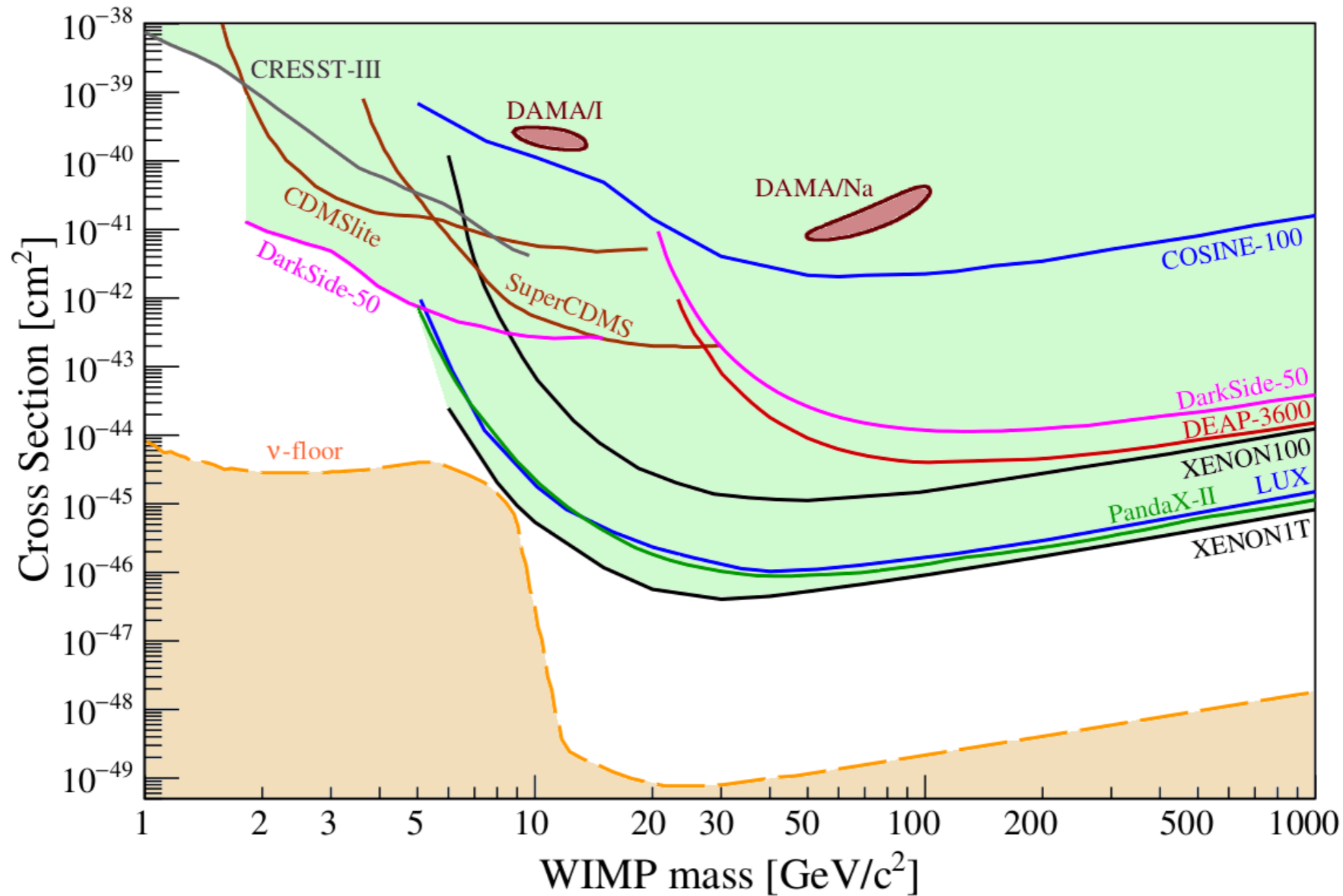
$$E_{det} = \frac{|\vec{q}|^2}{2m_N}$$

Insensitive to DM masses below $< \text{GeV}$

Nuclear Recoil Direct Detection



Nuclear Recoil Direct Detection



Current status: null results for weak scale DM

What about lighter DM (< GeV)?

Overview

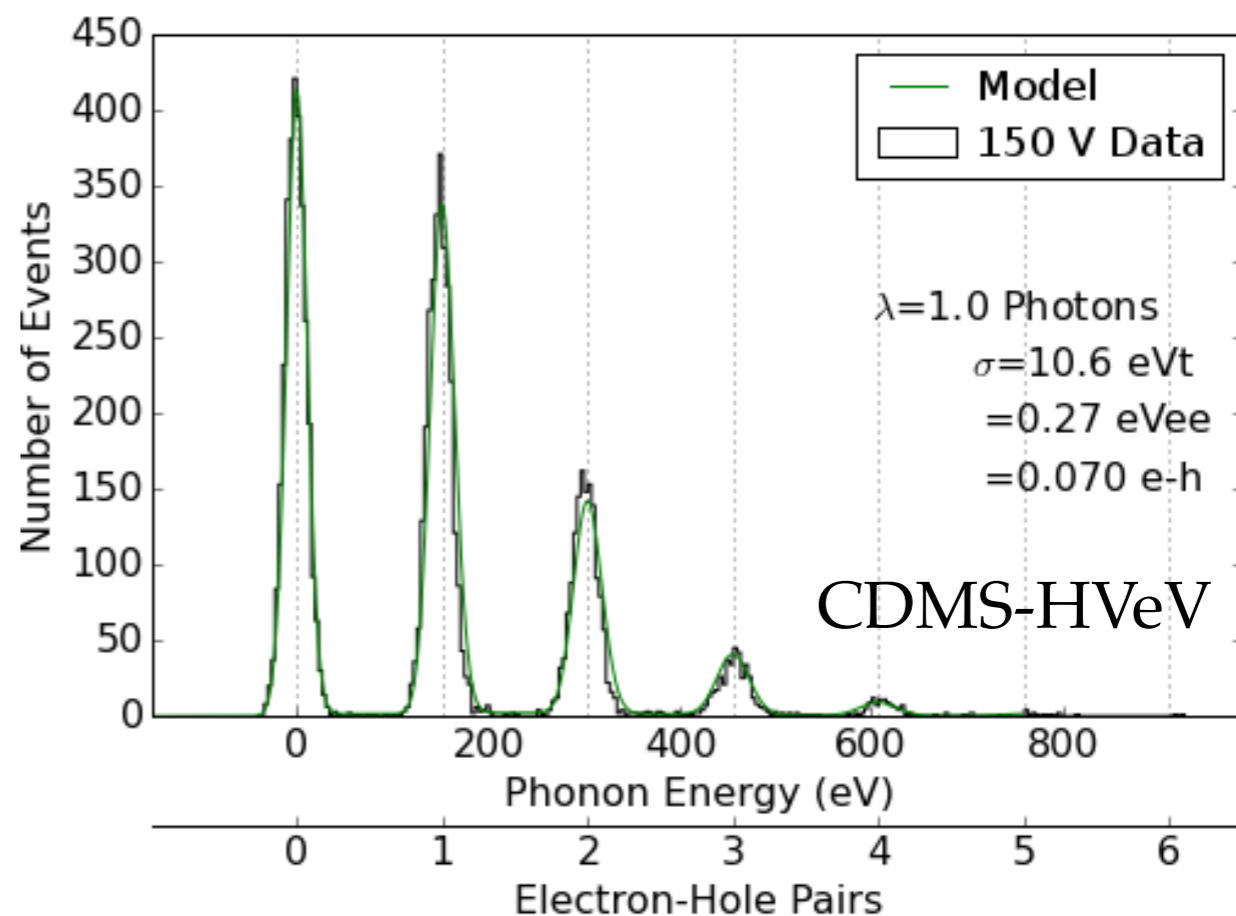
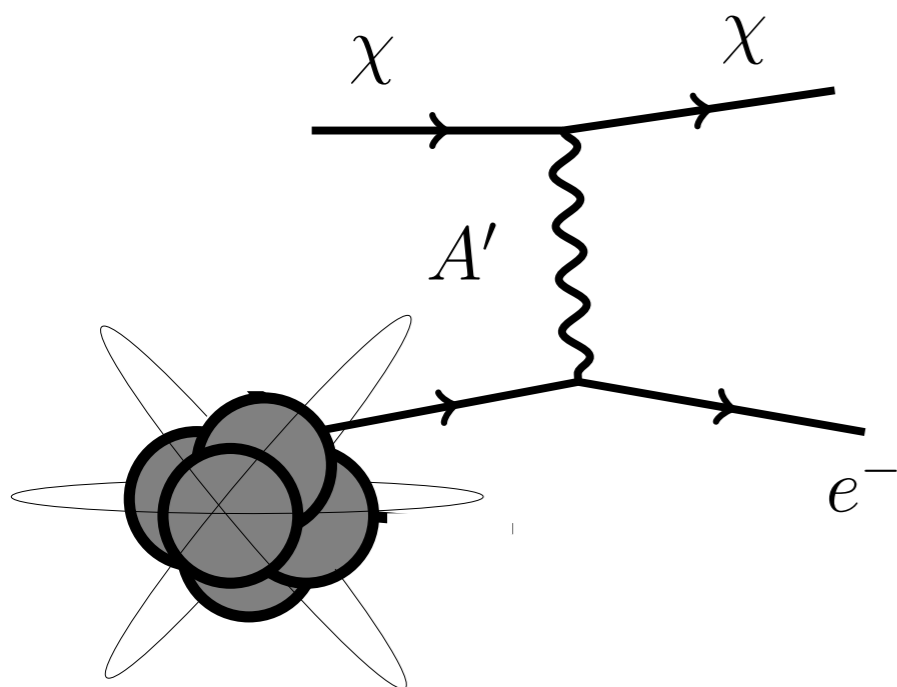
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- 2) There is a candidate process to characterize these events
- 3) Currently no known plausible SM explanation
- 4) This process may originate from DM interactions

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- 2) There is a candidate process to characterize these events
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Low Threshold Revolution

Lighter DD targets probe sub-GeV DM



Scatter electrons, not nuclei

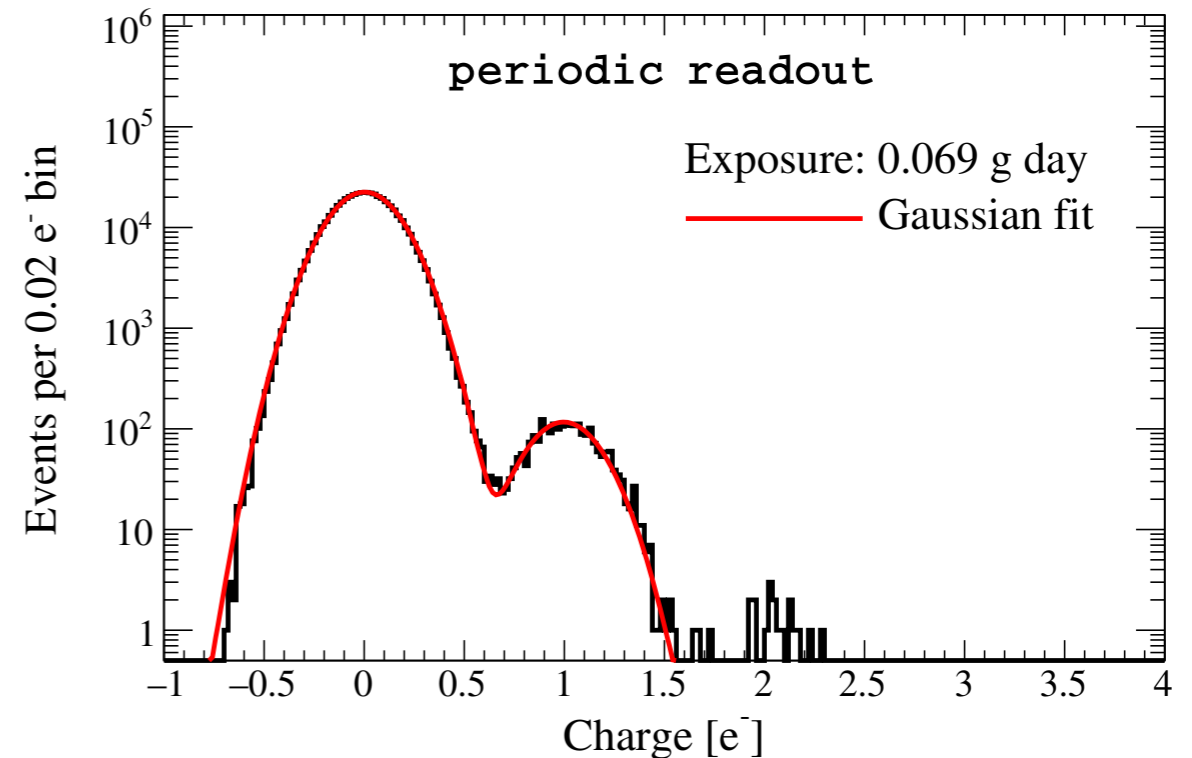
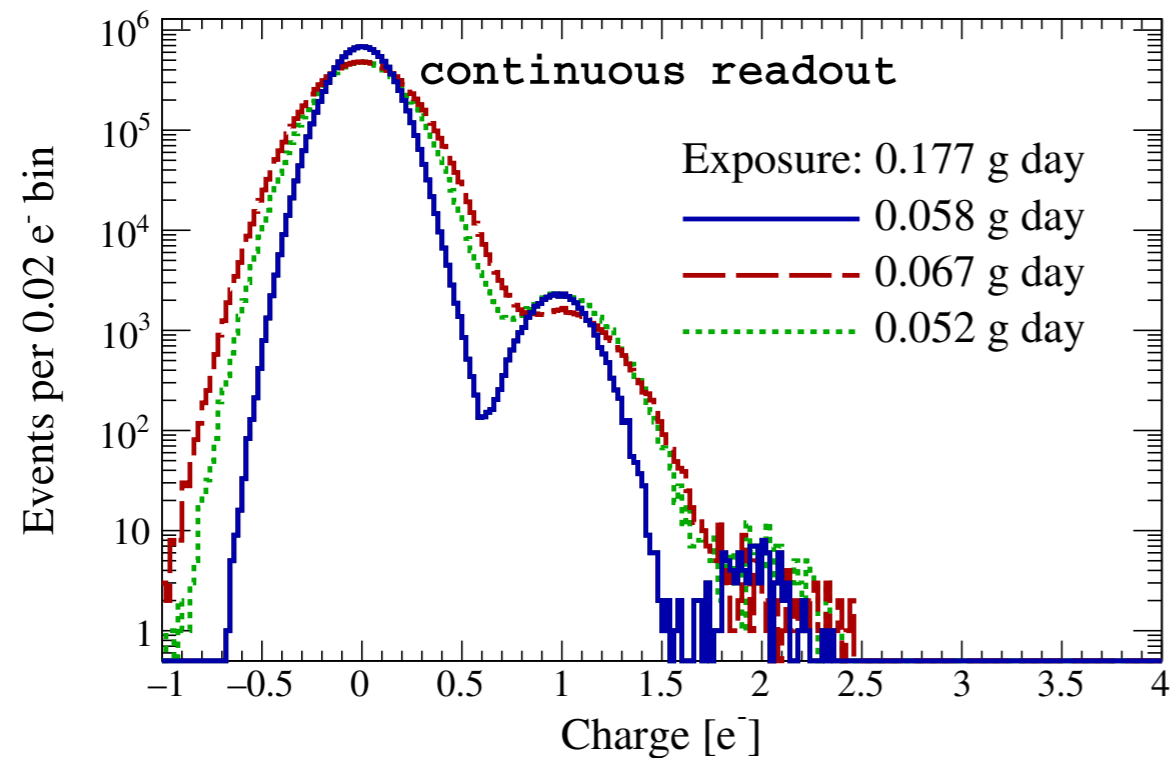
$$|\vec{q}| \sim m_e \alpha \quad , \quad E_e = \frac{|\vec{q}|^2}{2m_e}$$

Measure *ionization*
1-electron sensitivity

See Rouven Essig's slides

SENSEI (Charge Readout)

Silicon semiconductor

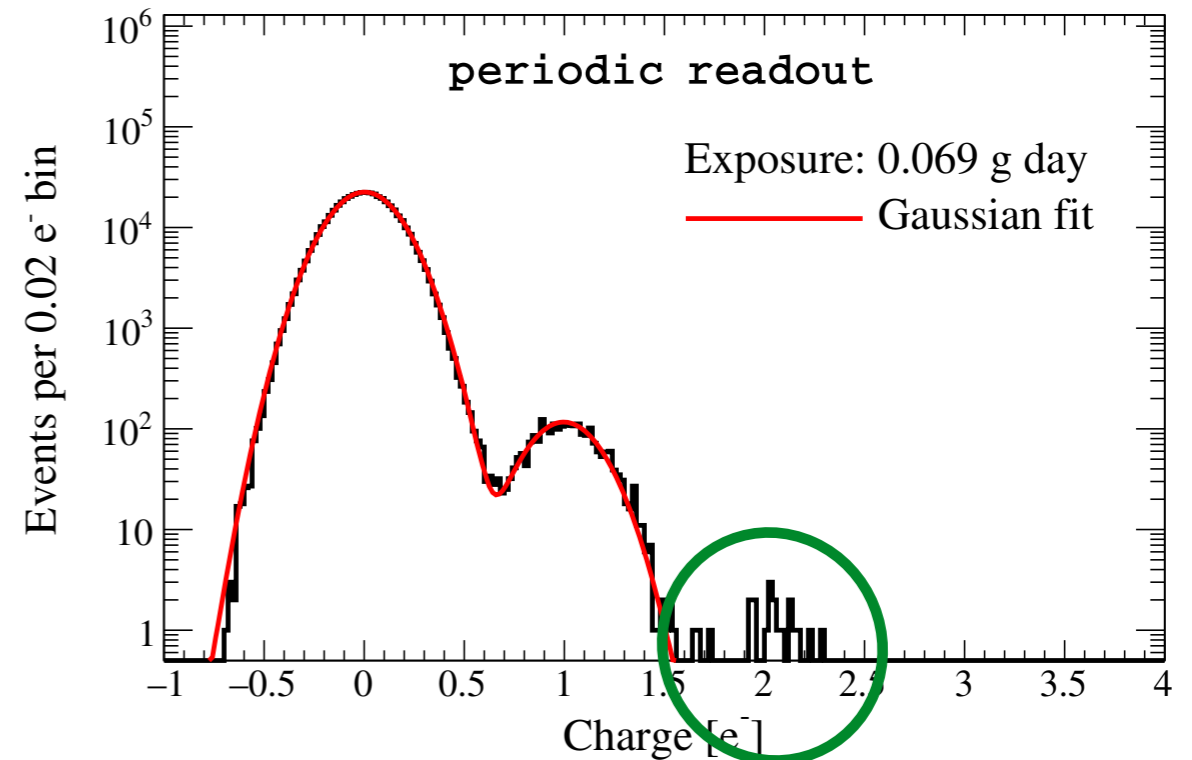
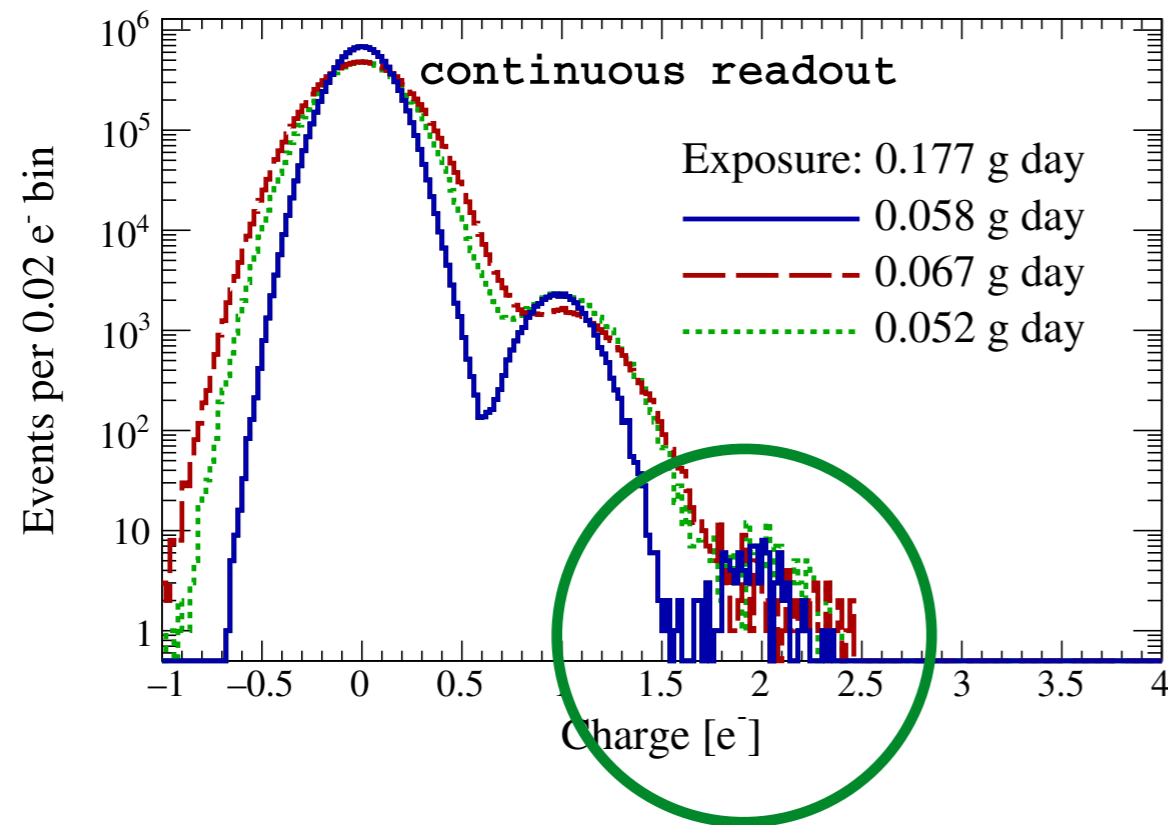


100 m detector depth
100 K temperature

0.2 e resolution
0.2 gram day exposure

SENSEI (Charge Readout)

Silicon semiconductor



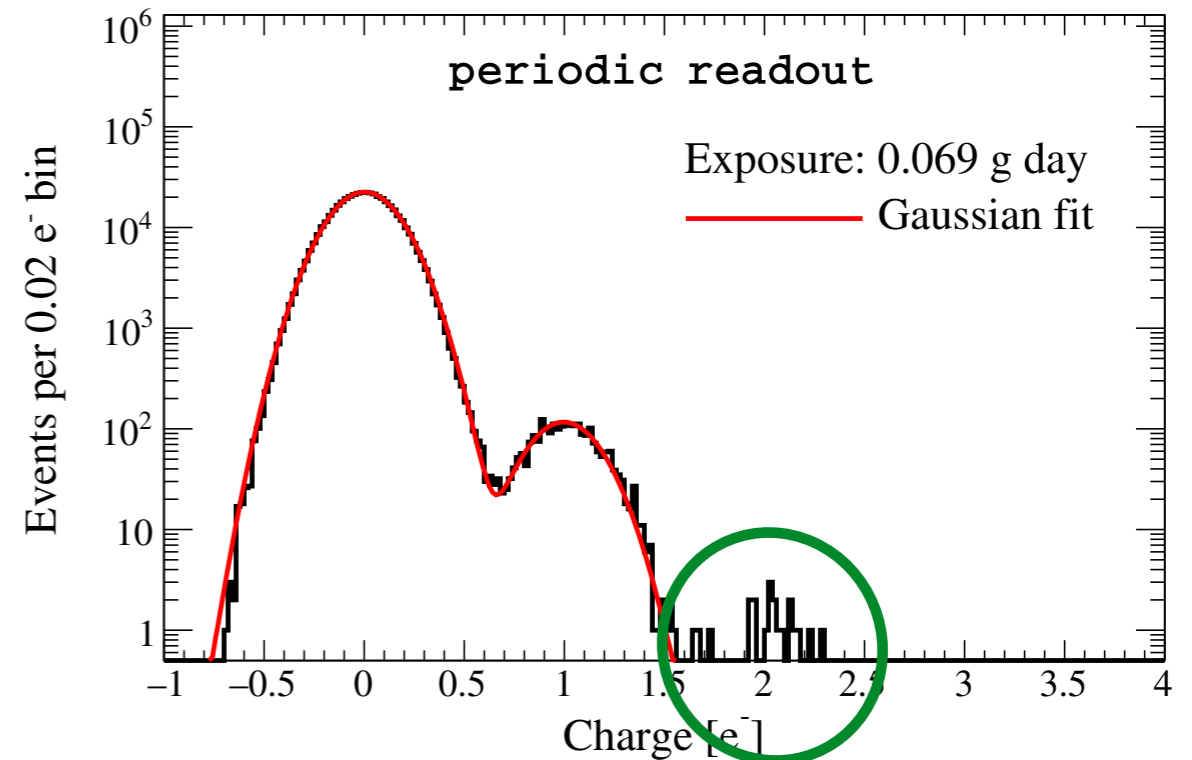
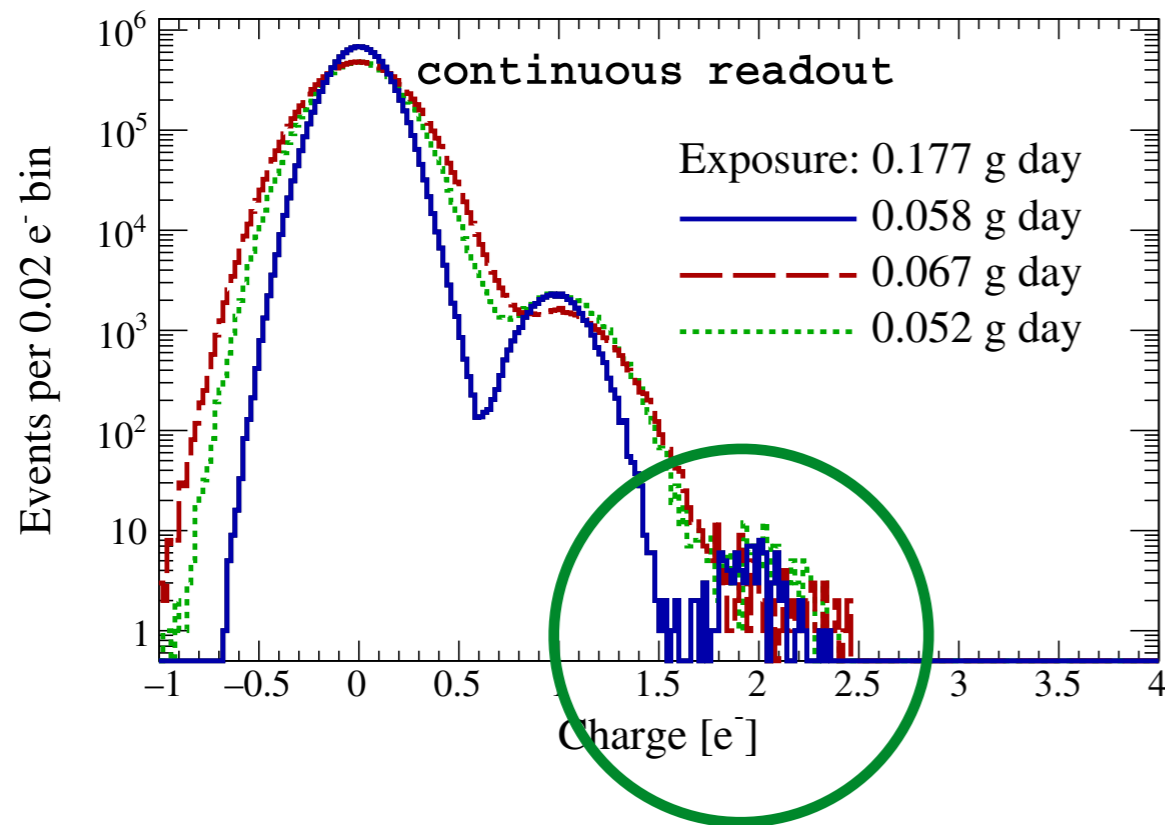
100 m detector depth
100 K temperature

0.2 e resolution
0.2 gram day exposure

Excess Rate = 6 - 400 Hz/kg

SENSEI (Charge Readout)

Silicon semiconductor



100 m detector depth

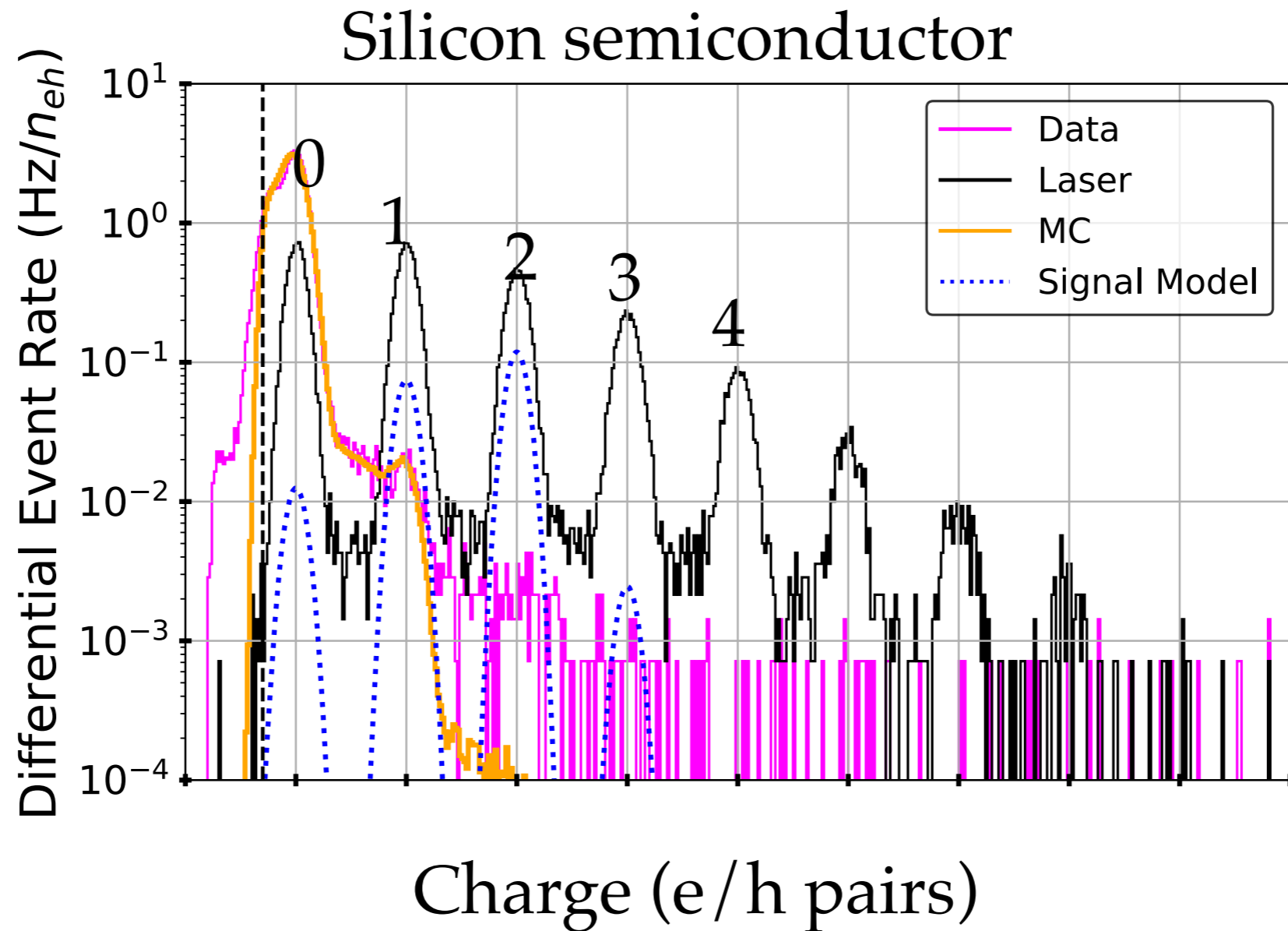
100 K temperature

April 2020 Update: Excess* Rate $\sim (0.01-1)$ Hz/kg

0.2 e resolution

0.2 gram day exposure

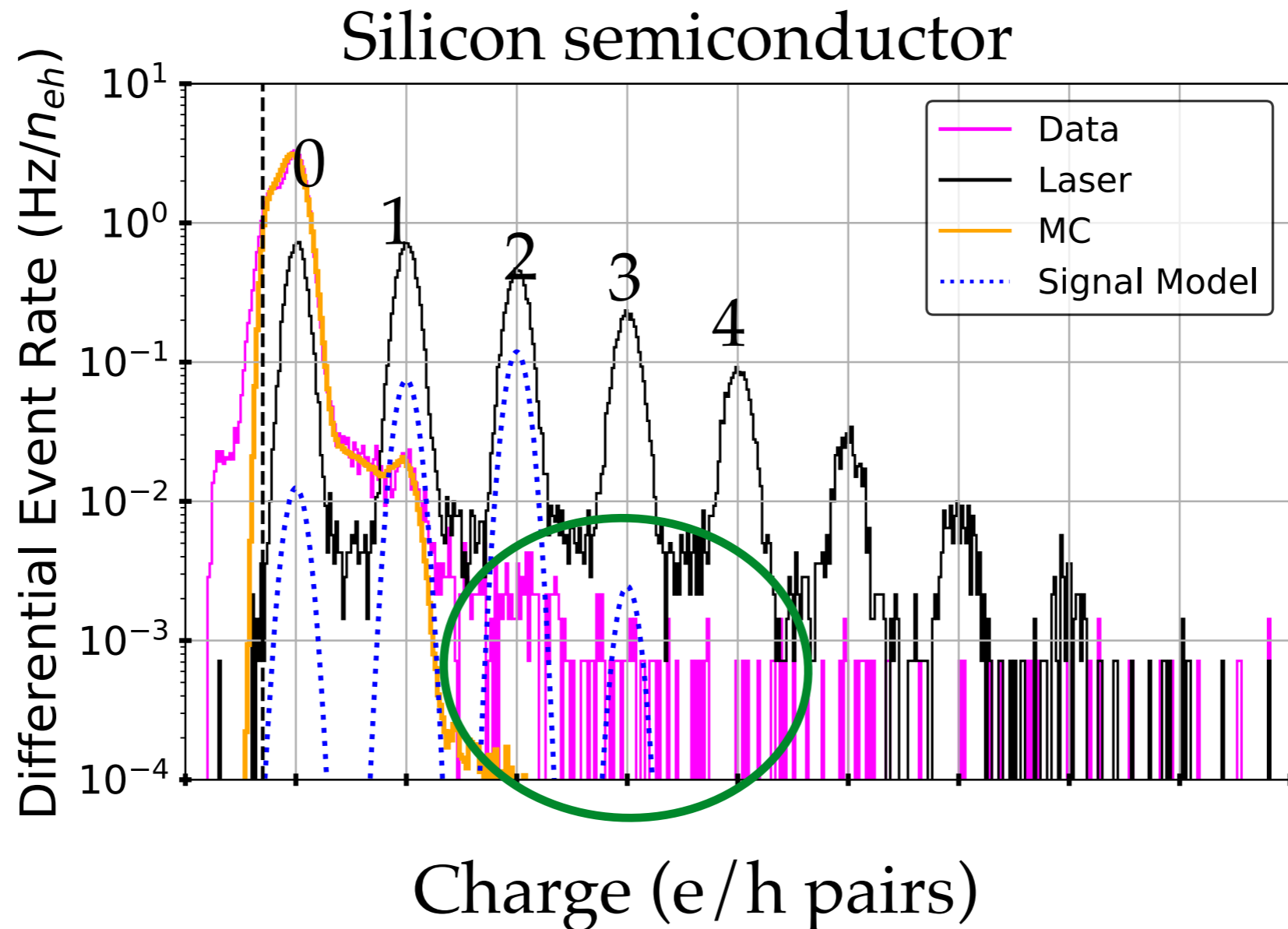
CDMS-HVeV (Charge Readout)



1 m detector depth
10 mK temperature

0.1 e resolution
0.5 gram day exposure

CDMS-HVeV (Charge Readout)



1 m detector depth

10 mK temperature

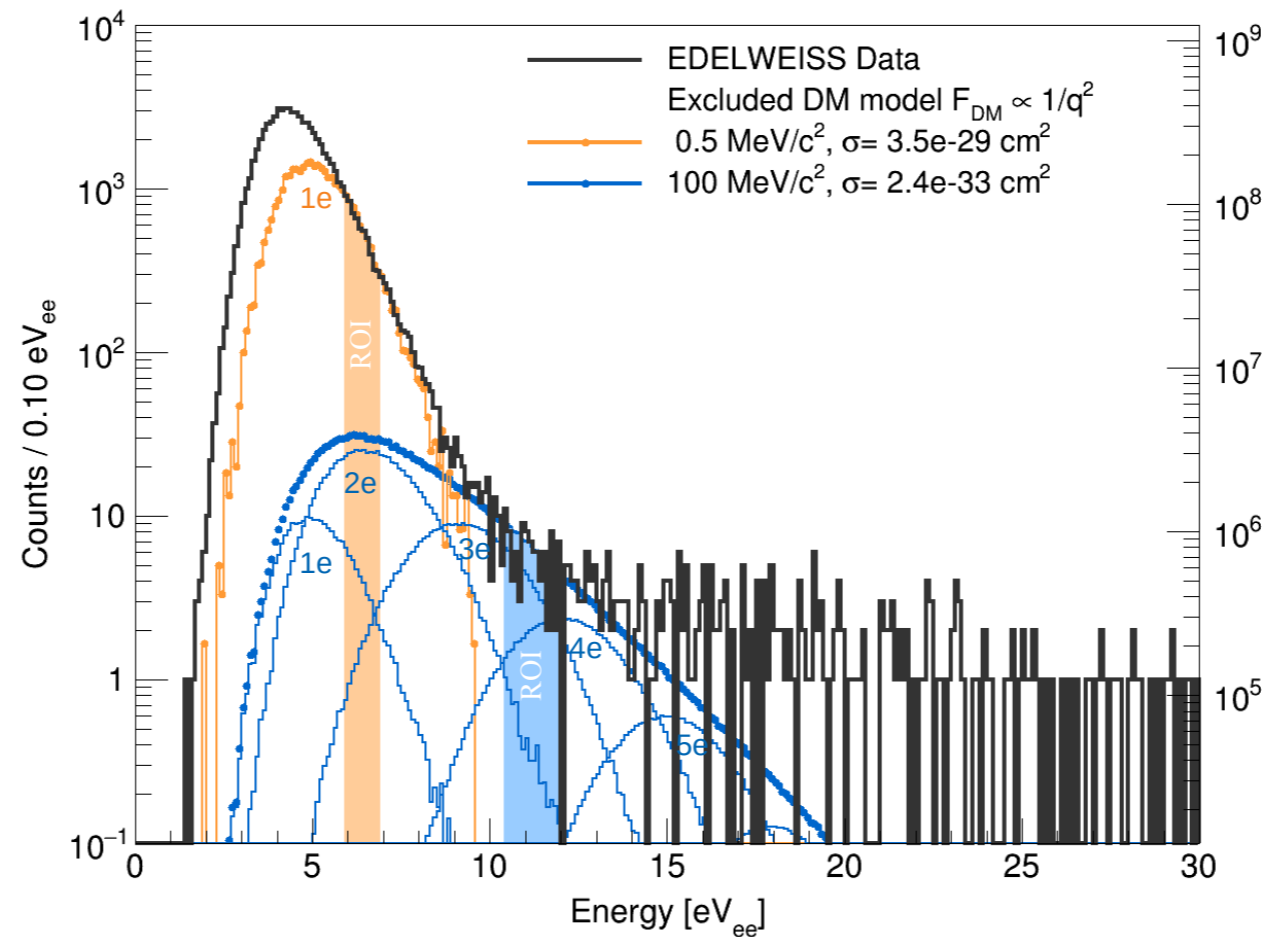
0.1 e resolution

0.5 gram day exposure

Excess Rate = 10 - 2000 Hz/kg (without / with 1e bin)

EDELWEISS (Charge Readout)

Germanium semiconductor

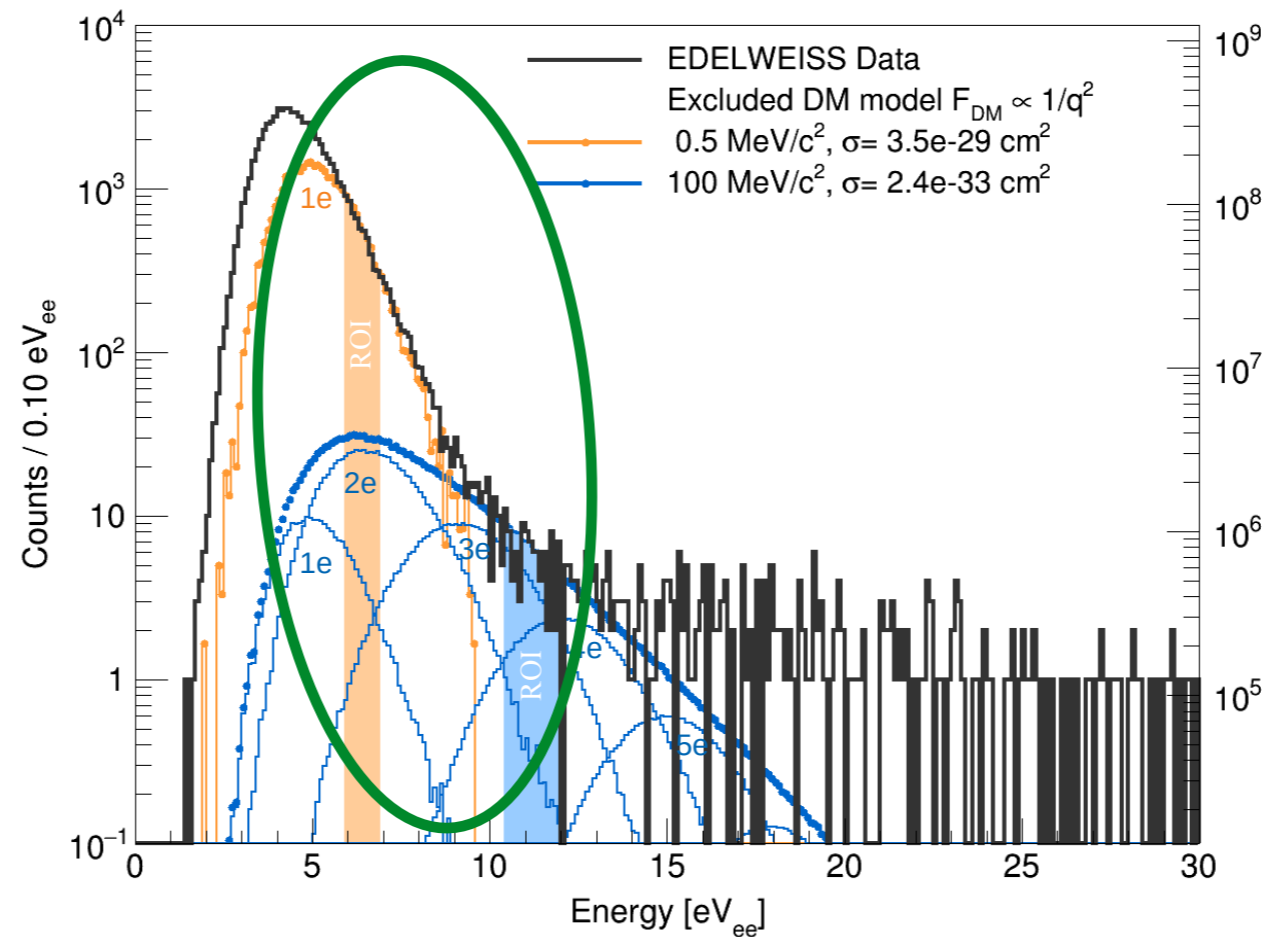


2 km detector depth
10 mK temperature

1.6 e resolution
80 gram day exposure

EDELWEISS (Charge Readout)

Germanium semiconductor



2 km detector depth

10 mK temperature

1.6 e resolution

80 gram day exposure

Excess Rate = 20 - 100 Hz/kg (without/with first bin)

DAMIC (Charge Readout)

CCD n.	σ_{pix} [e ⁻]	λ_d [e ⁻ mm ⁻² img ⁻¹]	μ_0 [e ⁻]	$\lambda = \lambda_{tot} - \lambda_d$ [e ⁻ mm ⁻² d ⁻¹]
1	1.628(1)	8.2(2)	-0.185(3)	2.8(2)
3	1.572(1)	7.8(2)	-0.160(4)	1.7(2)
4	1.594(1)	10.0(2)	-0.219(4)	1.0(2)
5	1.621(1)	8.5(2)	-0.183(4)	2.0(2)

DAMIC Collaboration PRL 1907.12628

2 km detector depth

100 K temperature

1.2 e resolution

200 gram day exposure

They report a low “dark count” rate $\sim 10^{-3}$ Hz/kg

DAMIC (Charge Readout)

CCD n.	σ_{pix} [e ⁻]	λ_d [e ⁻ mm ⁻² img ⁻¹]	μ_0 [e ⁻]	$\lambda = \lambda_{tot} - \lambda_d$ [e ⁻ mm ⁻² d ⁻¹]
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DAMIC Collaboration PRL 1907.12628

1) Uses a different ionization model from others

2) Reports “dark counts” based on likelihood analysis

Prior: all events treated as “dark count” BG

Could be misattributing would-be signal

Our interpretation: conservative upper bound ~ 7 Hz/kg

Semiconductor Summary

Readout Type	Target	Resolution	Exposure	Threshold	Excess Rate (Hz/kg)	Depth	Reference
Charge (E_e)	Ge	$1.6 e^-$	80 g·d	0.5 eVee ($\sim 1e^-$) ^a	[20, 100]	1.7 km	EDELWEISS [6]
	Si	$\sim 0.2 e^-$	0.18 g·d	1.2 eVee ($< 1 e^-$)	[6, 400]	100 m	SENSEI [4]
	Si	$0.1 e^-$	0.5 g·d	1.2 eVee ($< 1 e^-$)	[10, 2000]	~ 1 m	CDMS HVeV [3]
	Si	$1.6 e^-$	200 g·d	1.2 eVee ($\sim 1e^-$)	$[1 \times 10^{-3}, 7]$	2 km	DAMIC [7]

Intriguing coincidence of rates

Different Depths

Different Shielding

Different Exposures

Different Composition

Different Temperatures

Different Pressures

Unlike nuclear recoil: these are integrated total rates!

Semiconductors have tiny thresholds

All sub-GeV Searches Summary

Readout Type	Target	Resolution	Exposure	Threshold	Excess Rate (Hz/kg)	Depth	Reference
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Energy (E_{det})	Ge	18 eV	200 g·d	60 eV	> 2	~ 1 m	EDELWEISS [1]
	CaWO ₄	4.6 eV	3600 g·d	30 eV	$> 3 \times 10^{-3}$	0.4 km	CRESST-III [2]
	Al ₂ O ₃	3.8 eV	0.046 g·d	20 eV	> 30	~ 1 m	ν CLEUS [8]
Photo e^-	Xe	6.7 PE ($\sim 0.25 e^-$)	15 kg·d	12.1 eVee (~ 14 PE)	$[0.5, 3] \times 10^{-4}$	0.4 km	XENON10 [5, 9]
	Xe	6.2 PE ($\sim 0.31 e^-$)	30 kg·yr	~ 70 eVee (~ 80 PE)	$> 2.2 \times 10^{-5}$	0.4 km	XENON100 [5]
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	Ar	~ 15 PE ($\sim 0.5 e^-$)	6780 kg·d	50 eVee	$> 6 \times 10^{-4}$	0.4 km	Darkside50 [11]

Many others also observe excesses

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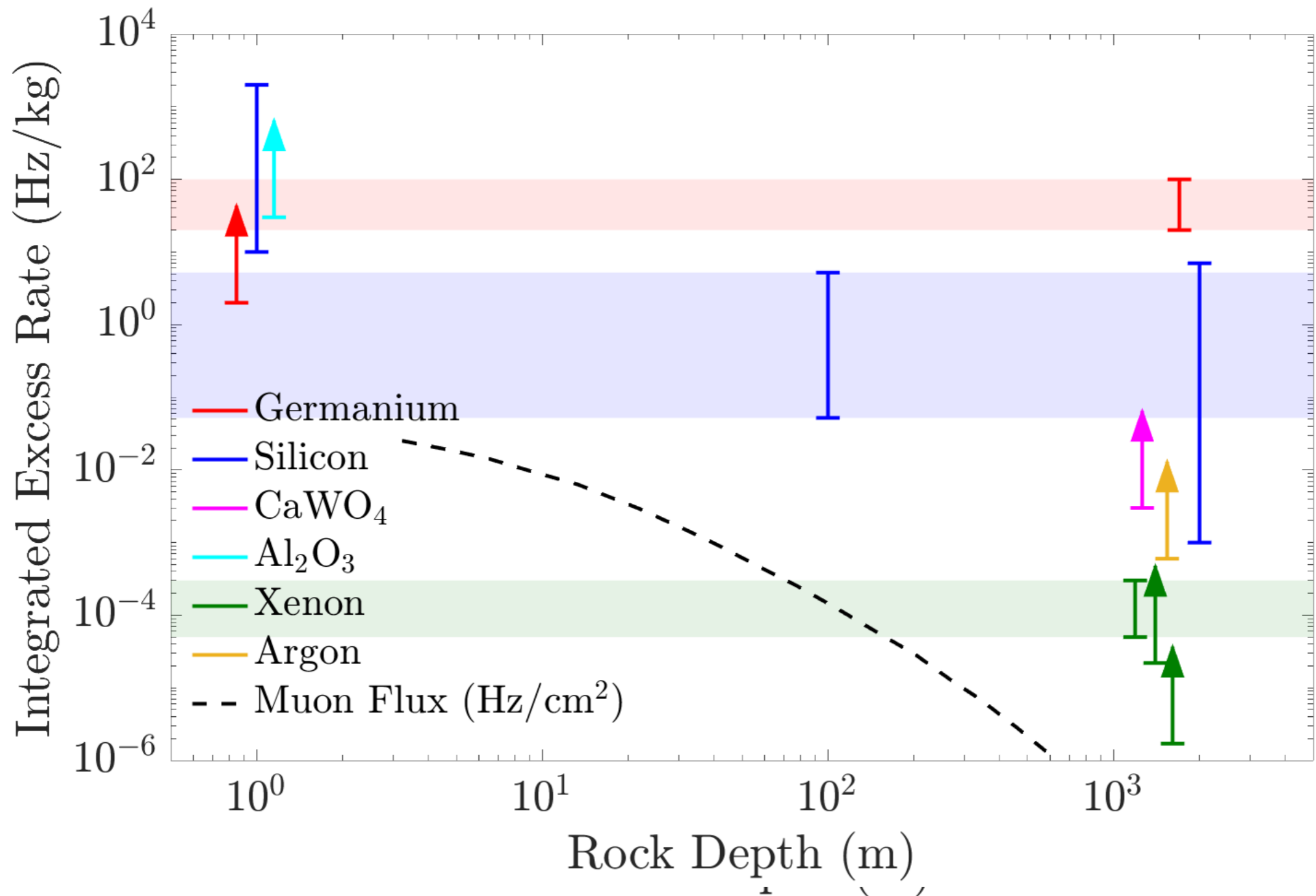
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-XENON10/100/1T rates all **similar for same threshold**

-EDELWEISS has excess in both E_e and E_{det} runs

Excesses vs. Depth



Overview

- 1) There are many weird direct-detection excesses
- 2) There is a candidate process to characterize these events**
- 3) Currently no known plausible SM explanation
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Why's Nobody Reporting a Signal?

EDELWEISS Case Study

EDELWEISS has data in both ER and NR

Both ER and NR runs observe excesses

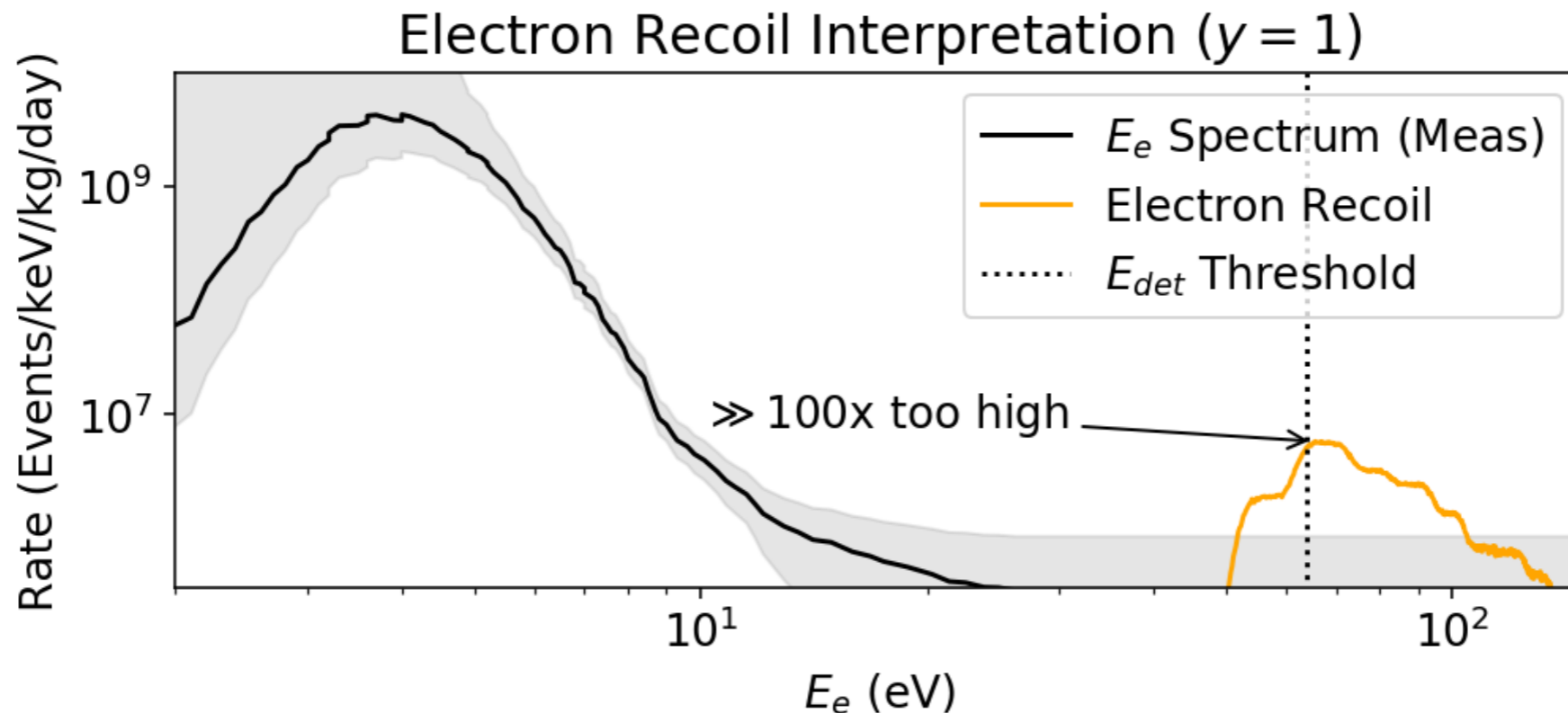
Interpreting these as the *same process* implies a charge model

$$E_e = E_{det} \left[y(E_{det}) + \frac{\epsilon_{eh}}{e \cdot V_{det}} \right]$$

Can we find a consistent description?

Electron Recoil Interpretation?

Assume EDELWEISS runs arise from DM-electron scattering

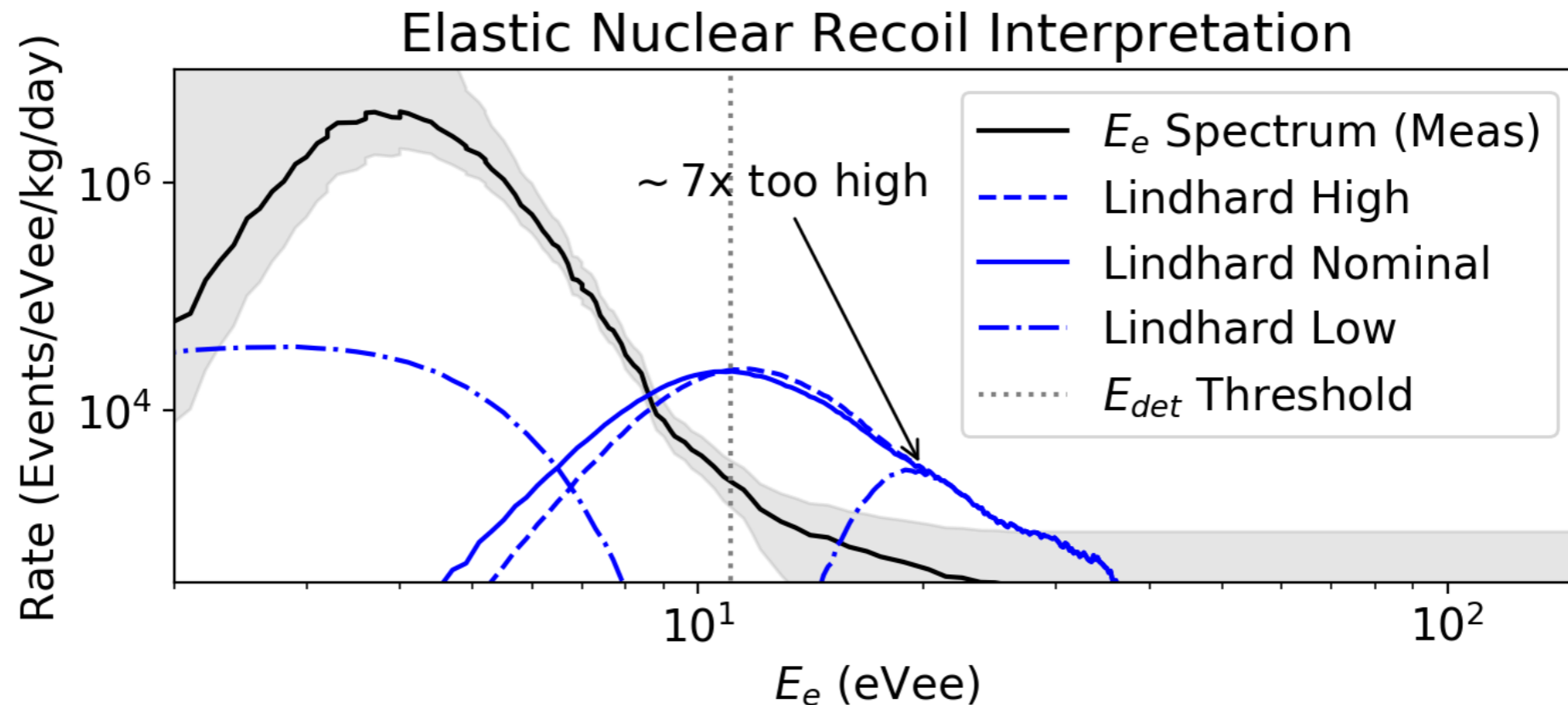


ER only prediction can't fit under black curve: BAD FIT

$$E_e = E_{det} \left[y(E_{det}) + \frac{\epsilon_{eh}}{e \cdot V_{det}} \right]$$

Nuclear Recoil Interpretation?

Assume EDELWEISS runs arise from DM-nucleon scattering



NR-only prediction can't fit under black curve: BAD FIT

$$E_e = E_{det} \left[y(E_{det}) + \frac{\epsilon_{eh}}{e \cdot V_{det}} \right]$$

Another Possibility?

Assume the excess is due to some inelastic* process

$$\langle E_e \rangle = \epsilon_{eh} \left(\lambda_{eh} + \frac{E_{det}}{e \cdot V_{det}} \right)$$

Electron/hole pair
energy

Average e/h yield
per signal event

Total det
energy

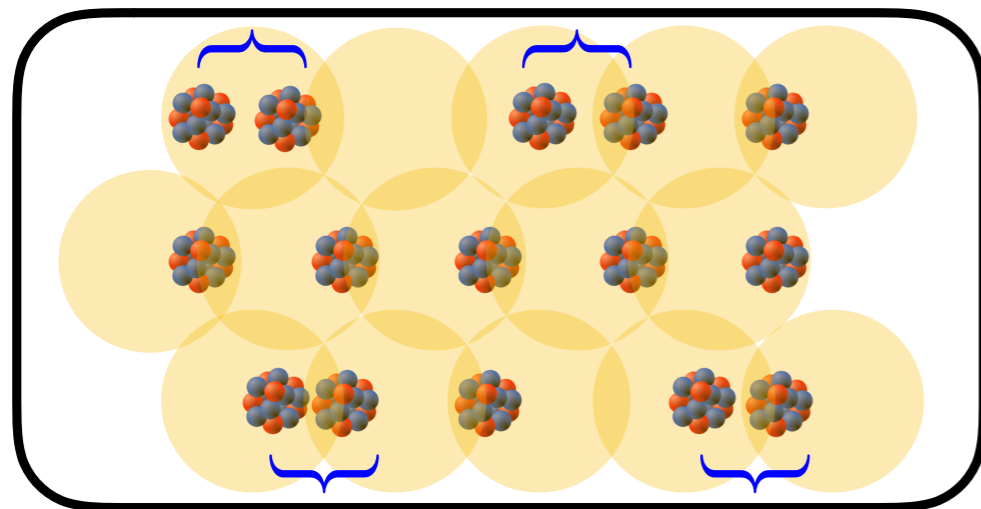
Key feature: constant piece independent of E_{det}

*Not to be confused with inelastic DM!

Consider Semiconductor Plasmons

Long wavelength charge oscillation between electrons / ions
>> lattice spacing

phonons (momentum)



plasmon (energy)

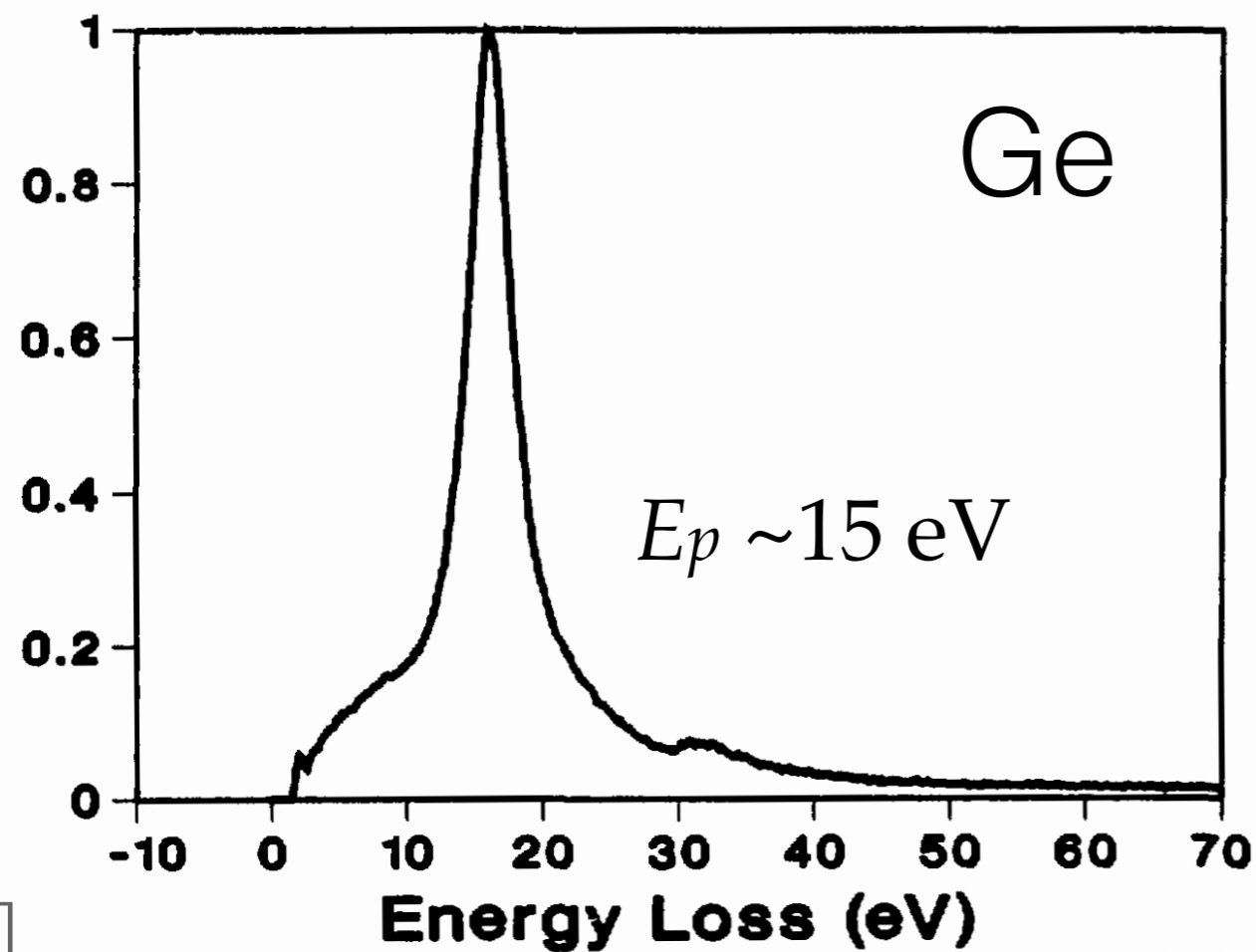
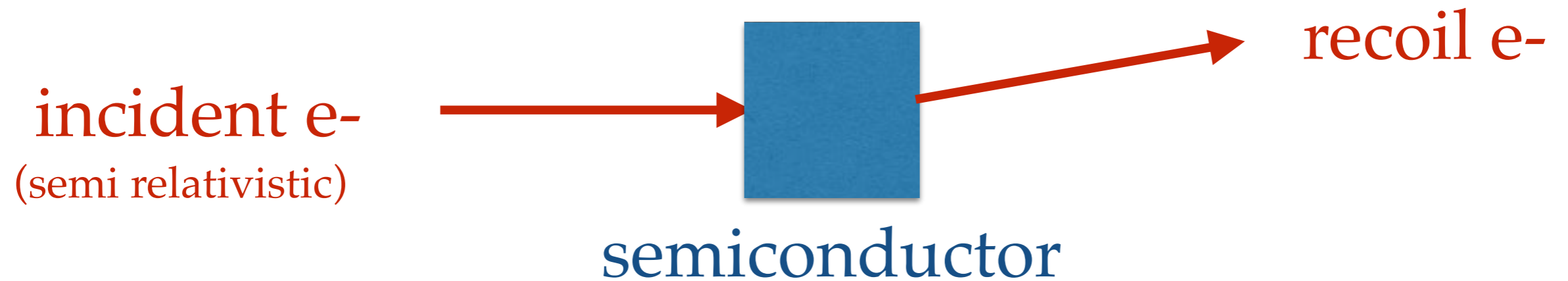
Plasmon excitation energy

$$E_p \simeq \sqrt{\frac{4\pi\alpha n_e}{m_e}}$$

Low-P standing wave decays to e/h pairs or phonons

Breaks usual charge heat yield relationship

Analogy: Electron Energy Loss Spectroscopy (EELS)

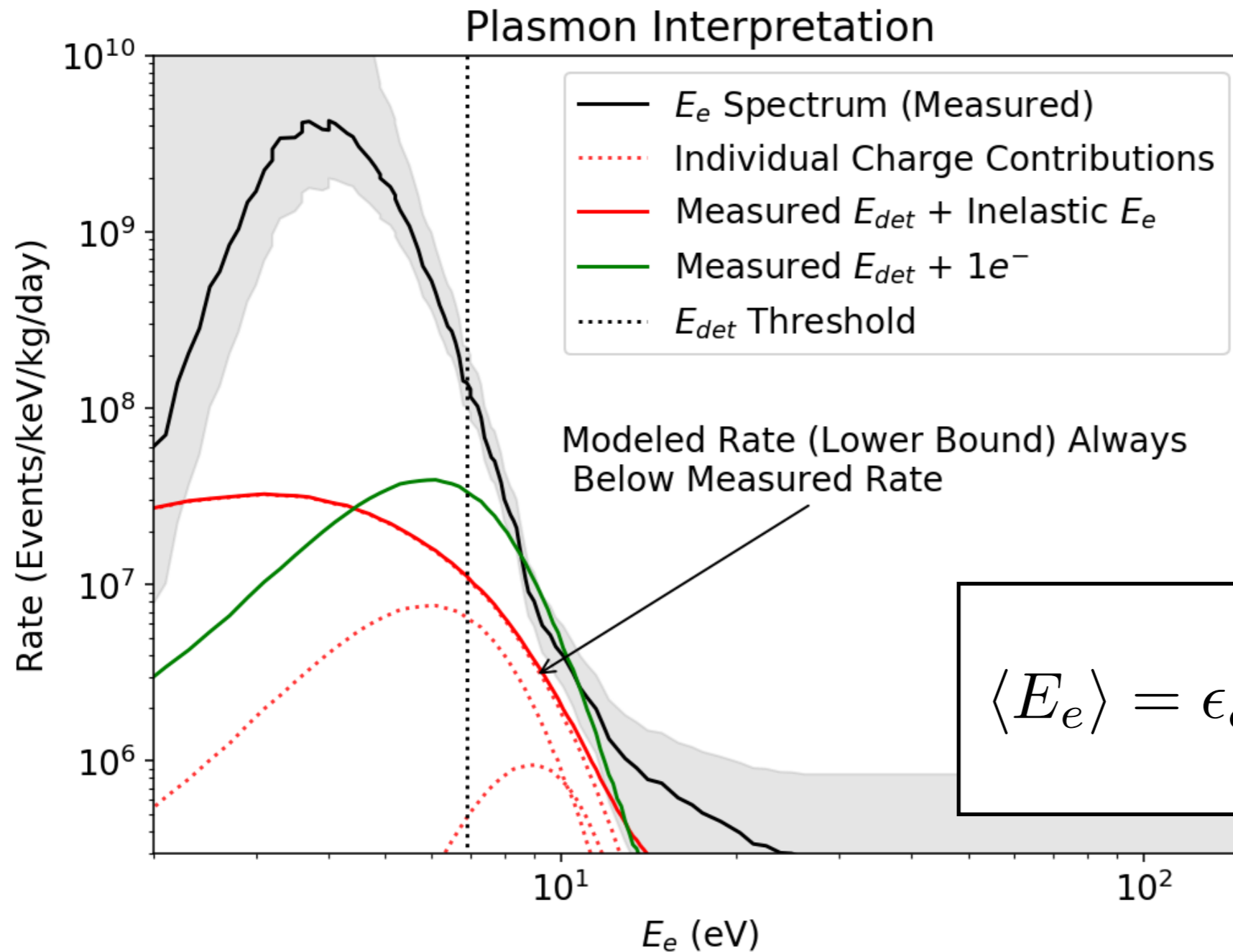


$$E_{det} \sim E_p \sim 15 \text{ eV}$$

independent of initial velocity

Qualitatively different
charge/heat yield relation

“Inelastic” Yield Model



$$\langle E_e \rangle = \epsilon_{eh} \left(\lambda_{eh} + \frac{E_{det}}{e \cdot V_{det}} \right)$$

Key point: model can now fit under black curve

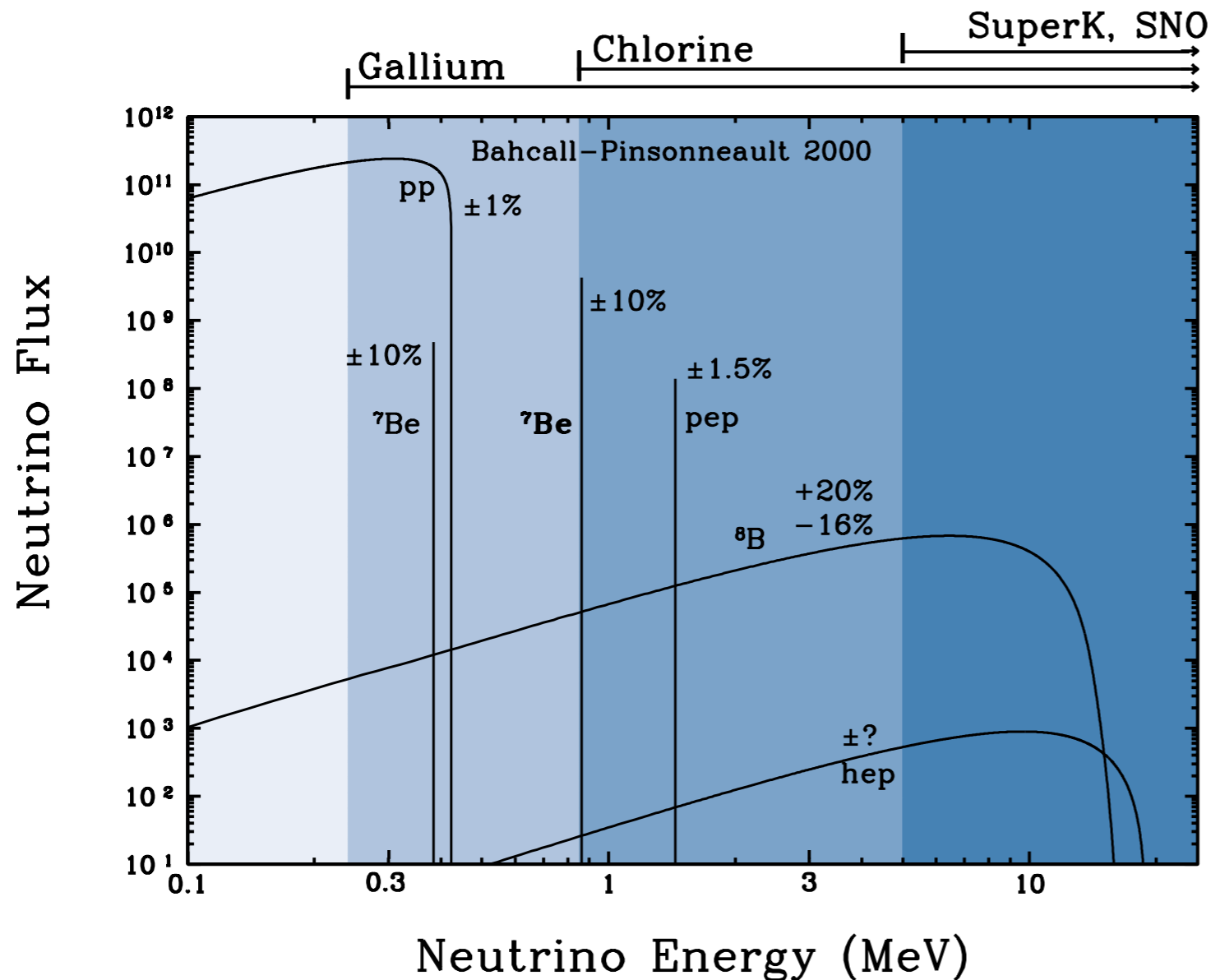
General result not limited to plasmons

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Solar pp Neutrinos?

Most abundant terrestrial neutrino flux



Can't make plasmon

$$E_R \sim \frac{2E_\nu^2}{M_{\text{Ge}}} \sim 5 \text{ eV} \left(\frac{E_\nu}{400 \text{ keV}} \right)^2$$

need $\sim 16 \text{ eV}$ in Ge

$$\mathcal{R}_{pp} = N_{\text{Ge}} \Phi_{pp} \sigma_{pp}^{\text{coh}} \simeq 2.3 \times 10^{-6} \text{ Hz kg}^{-1} \quad \dots \text{ and flux too low}$$

Photons / Electrons?

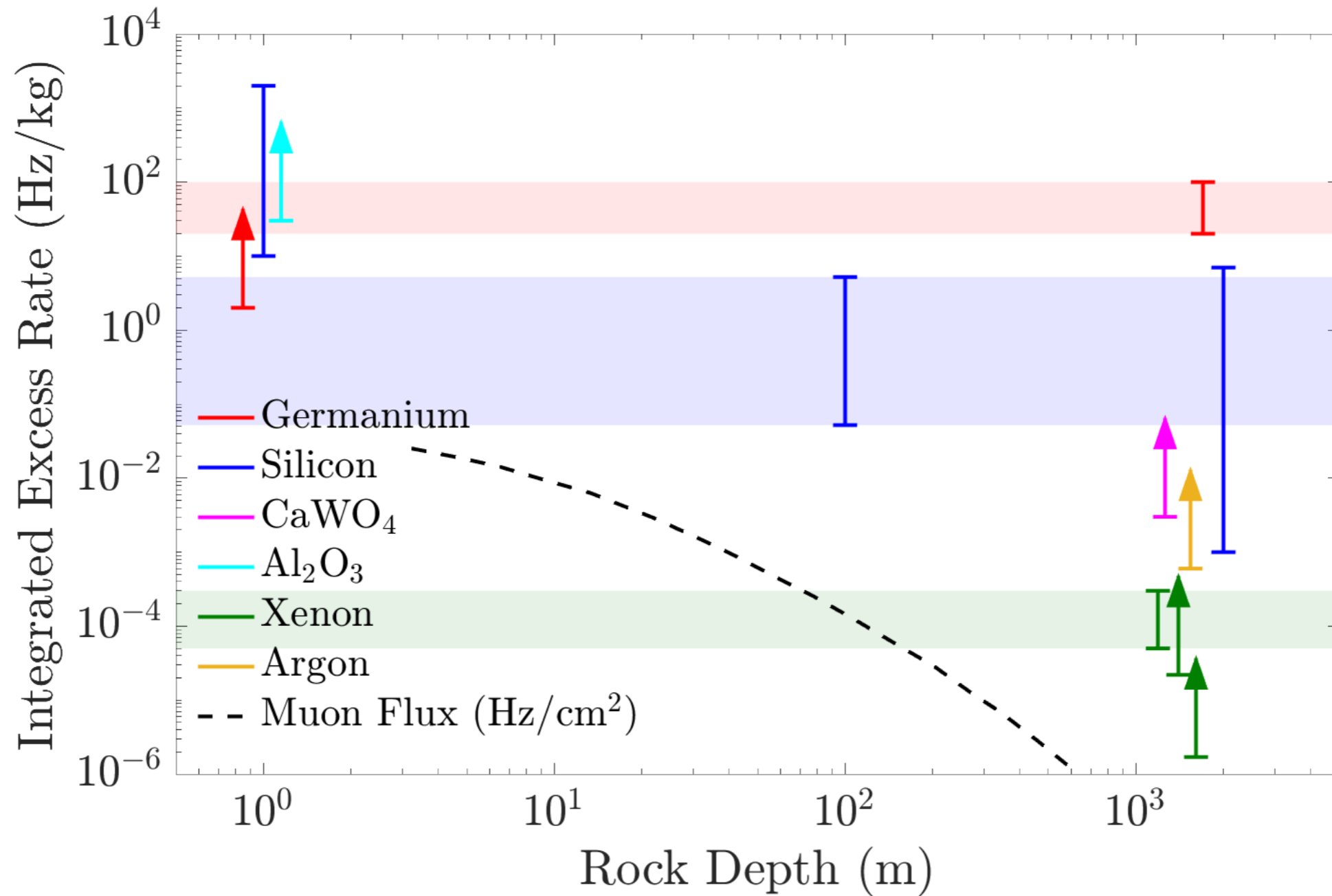
Photons: Transversely polarized & can't source plasmons which are longitudinally polarized

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Would multiple scatter and create many plasmons

Not observed: need single energy deposit < 100 eV

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Muon flux has known scaling with depth

Neutrons?

Possible in principle

Neutron could scatter nucleus, excite secondary plasmon

Possible calibration strategy

Baxter, Kahn, Kurinsky, GK [in preparation]

Hard to explain all excesses this way

Different Depths

Different Shielding

Different Exposures

Different Composition

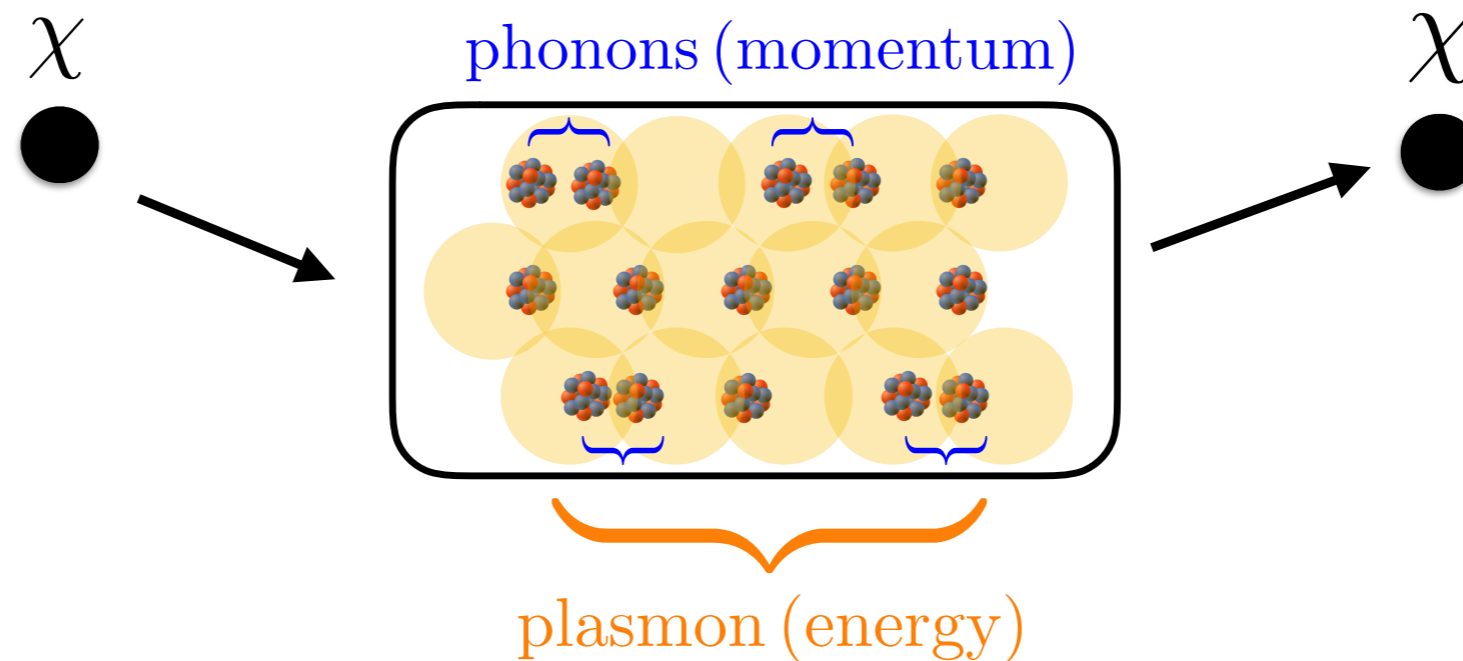
Why is the neutron flux independent of these factors?

Overview

- 1) There are many weird direct-detection excesses
- 2) There is a candidate process to characterize these events
- 3) **This process may originate from DM interactions**
 - a) **Direct Plasmon Excitation**
 - b) **Secondary Plasmon Excitation**

a) Direct Plasmon Excitation Model

Extend EELS analogy: “millicharged” DM



DM excites plasmon directly through its own Coulomb field

Longer mean free path, $\ll 1$ interaction per crossing

a) Direct Plasmon Excitation Model

Can use measured EELS plasmon excitation prob.

$$\frac{dP}{dt d\omega} = \frac{e^2}{4\pi^3} \int d^3\mathbf{q} \frac{1}{q^2} \text{Im} \left\{ \frac{-1}{\epsilon(\omega, \mathbf{q})} \right\} \\ \times \delta \left(\omega - \mathbf{q} \cdot \mathbf{v} + \frac{q^2}{2m_\chi} \right)$$

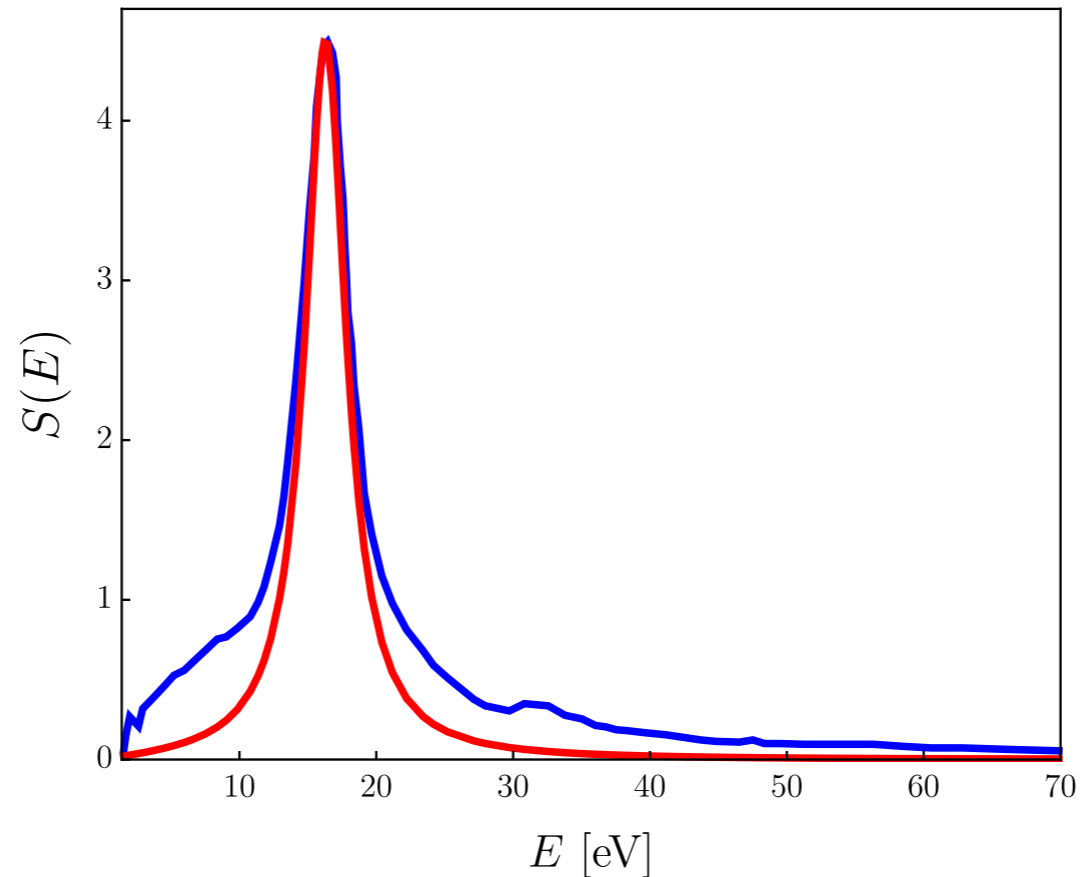
Need forward scatter ($\cos > 0$) for low q -transfer

$$q = \frac{E}{v \cos \theta} + \frac{q^2}{2m_\chi v \cos \theta} \longrightarrow v \geq E_p/q_p = 6.5 \times 10^{-3} \left(\frac{E_p}{16 \text{ eV}} \right)$$

Minimum (high!) velocity for direct plasmon excitation

a) Direct Plasmon Excitation Model

Approximate shape with Lorentzian fit (Frolich model)

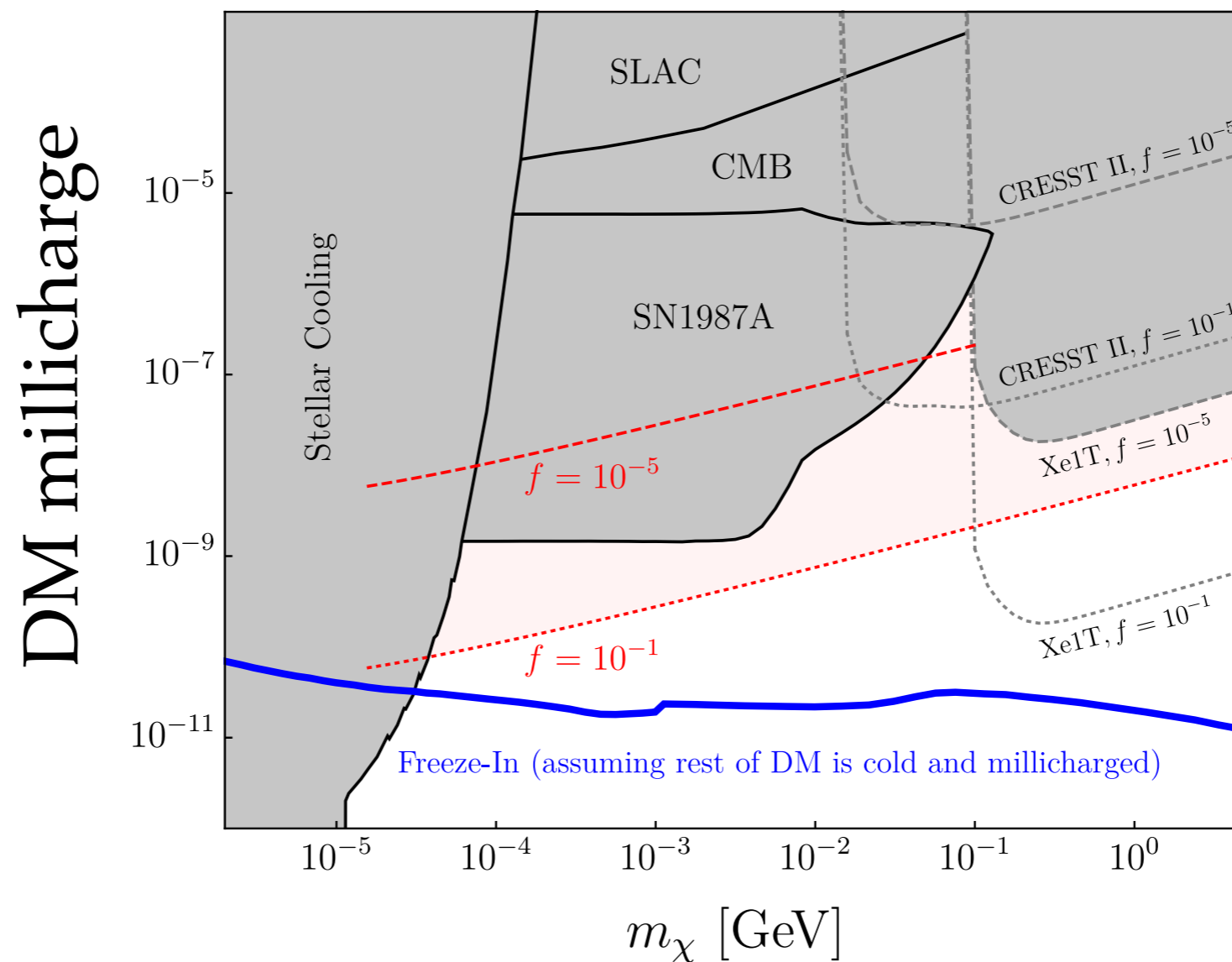


Completely calculable (rescale EELS rate by charge)

$$\frac{dR}{dE} = \frac{f\rho_{\chi}}{m_{\chi}\rho_T} \frac{2\kappa^2\alpha_D}{\pi} S(E) \int_0^{q_c} \frac{dq}{q} \eta(v_{\min}(q, E))$$

a) Direct Plasmon Excitation Model

Need fraction f of DM population with boosted velocity



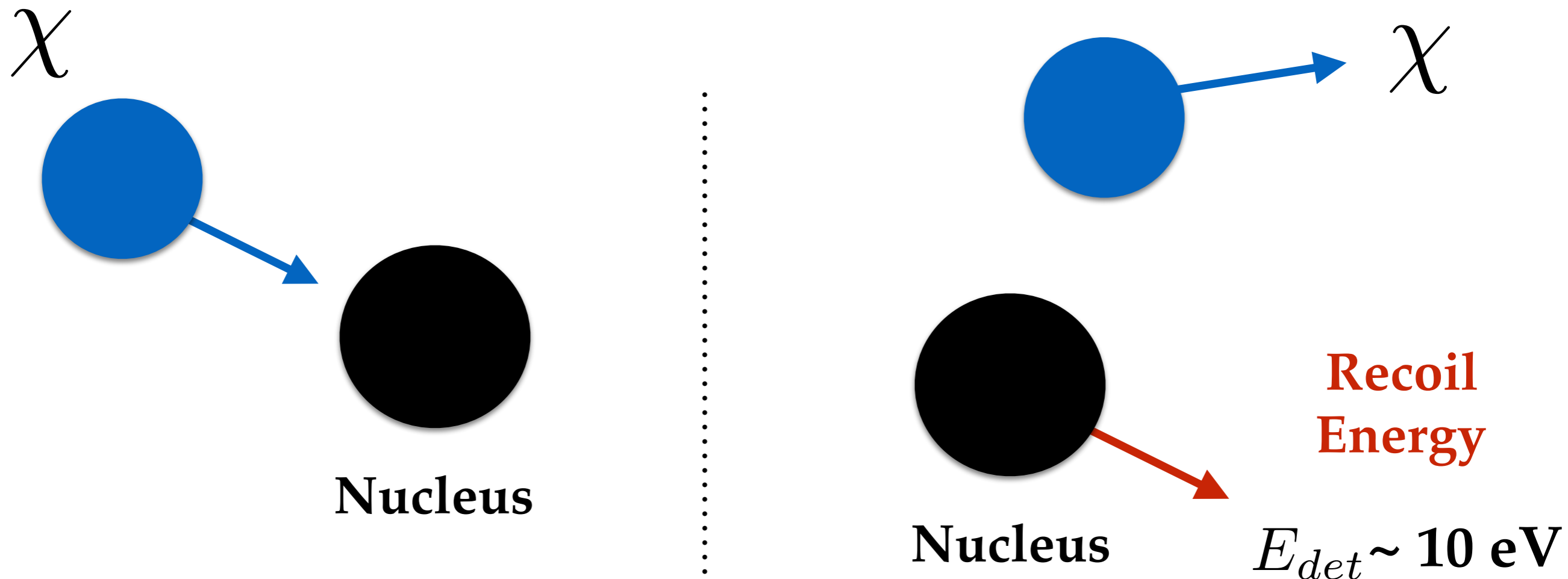
Here
 $v \sim 0.1$

Shaded region ~ 10 Hz/kg in Ge

Overview

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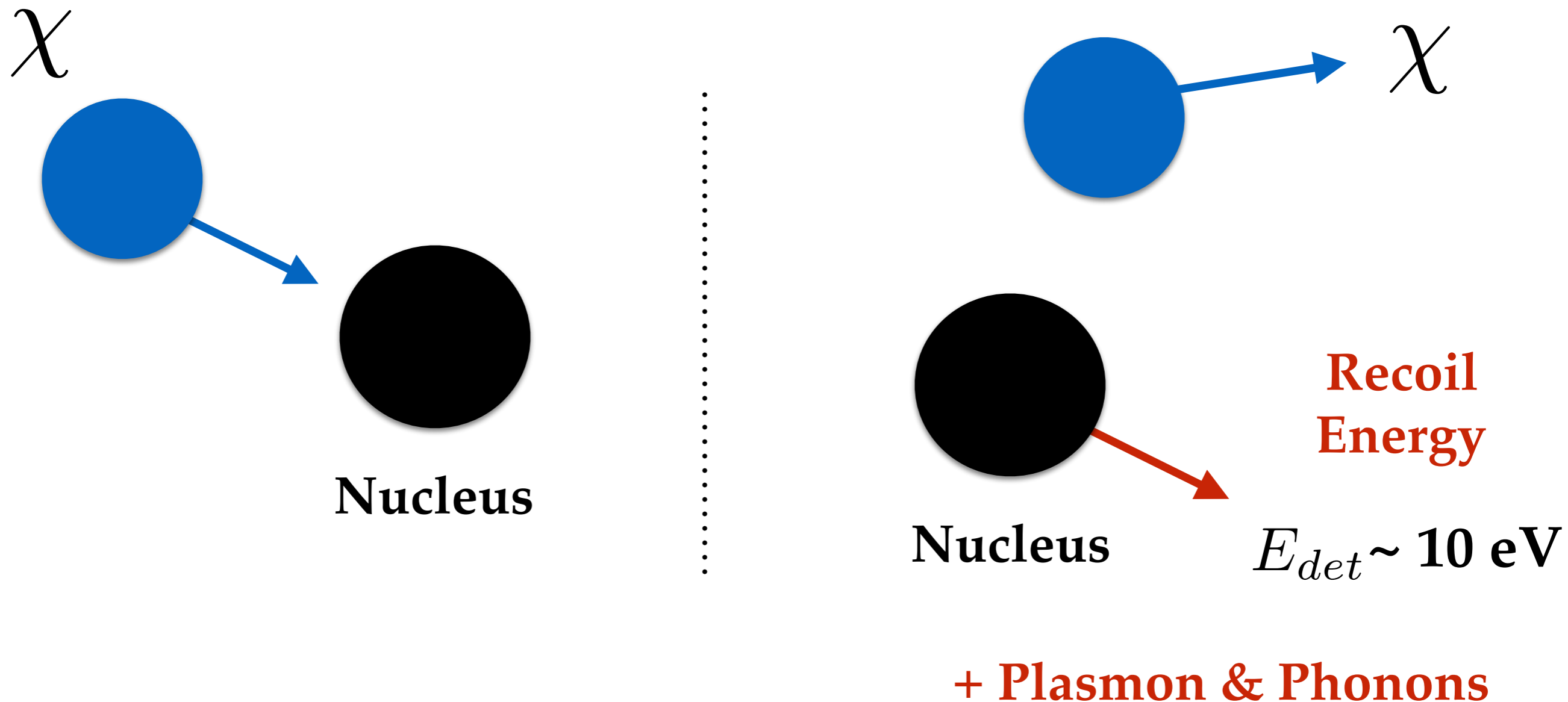
Secondary Plasmon Excitation Model



Step 1: DM induces a feeble nuclear recoil

Contact interaction, conventional DM velocity

Secondary Plasmon Excitation Model



Step 2: Nuclear recoil triggers plasmon excitation

See also Lin & Kozaczuk 2003.12077 for plasmon + single phonon study

Secondary Plasmon Excitation Model

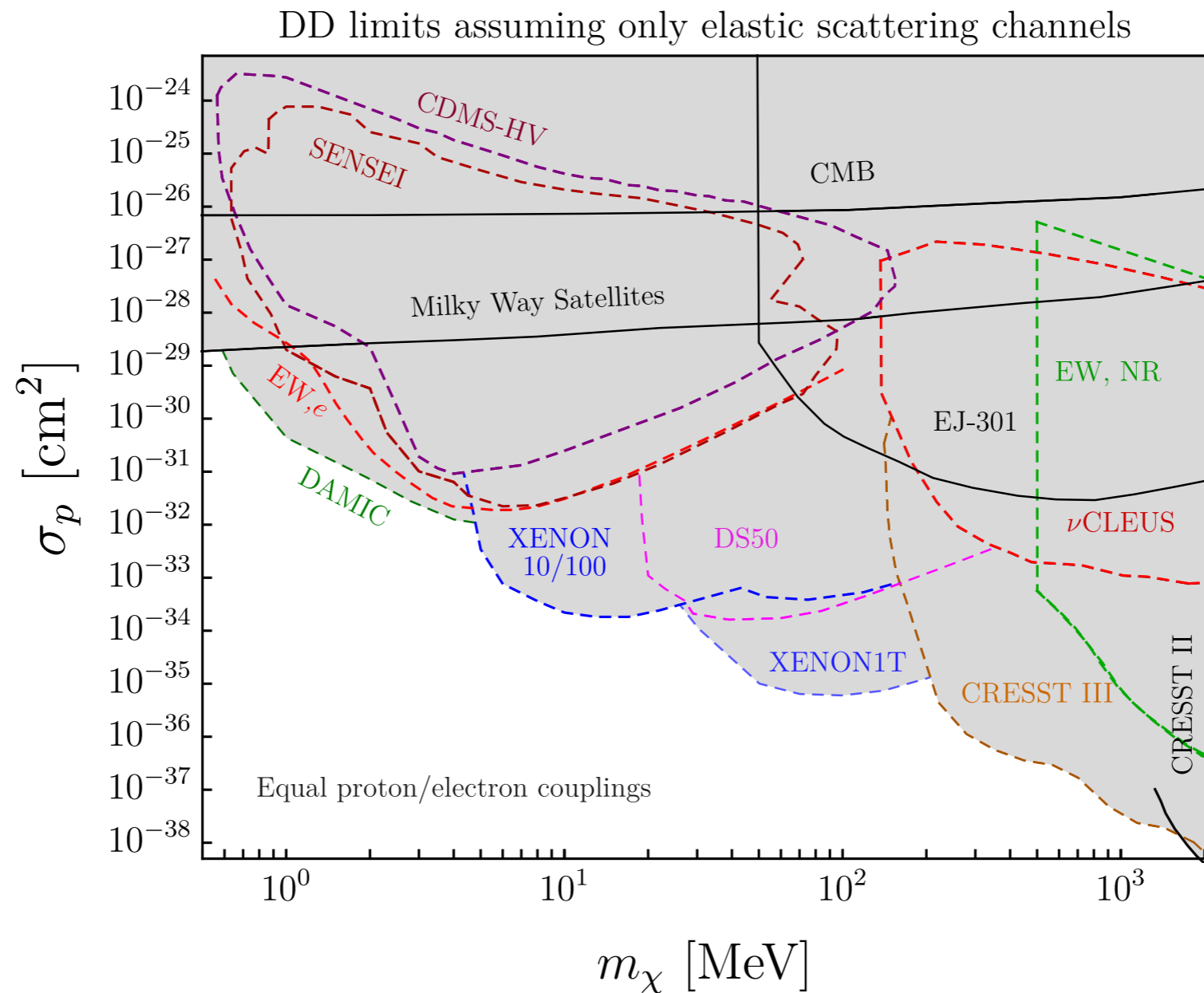
Unlike millicharged scenario:

- 1) Use 100% of the DM population
- 2) Use the usual DM velocity distribution
- 3) Can't calculate secondary plasmon excitation rate

$$R \sim N_T \mathcal{P} \frac{\rho_\chi}{m_\chi} \sigma_n v,$$

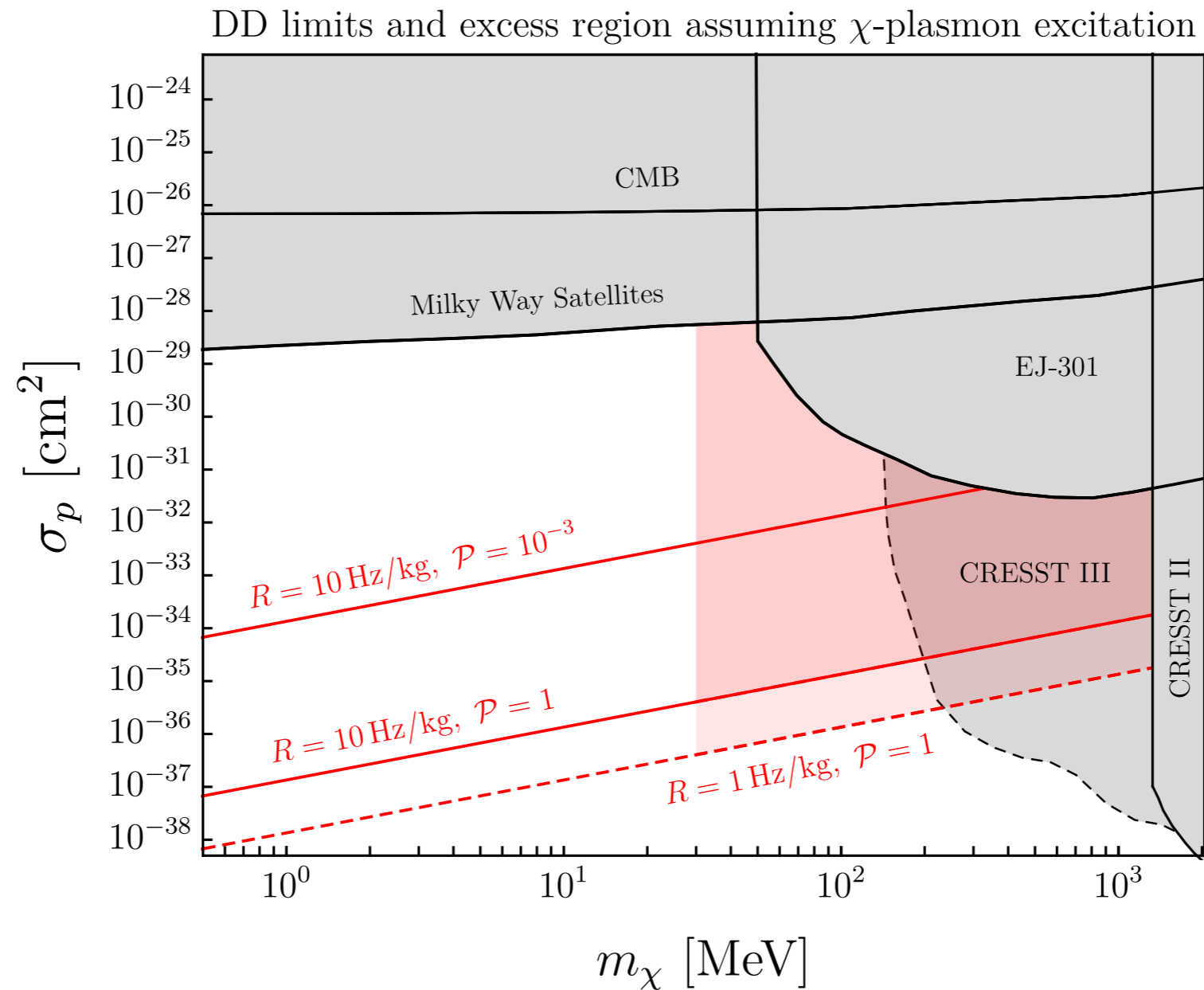
Parametrize our ignorance

Secondary Plasmon Excitation Model



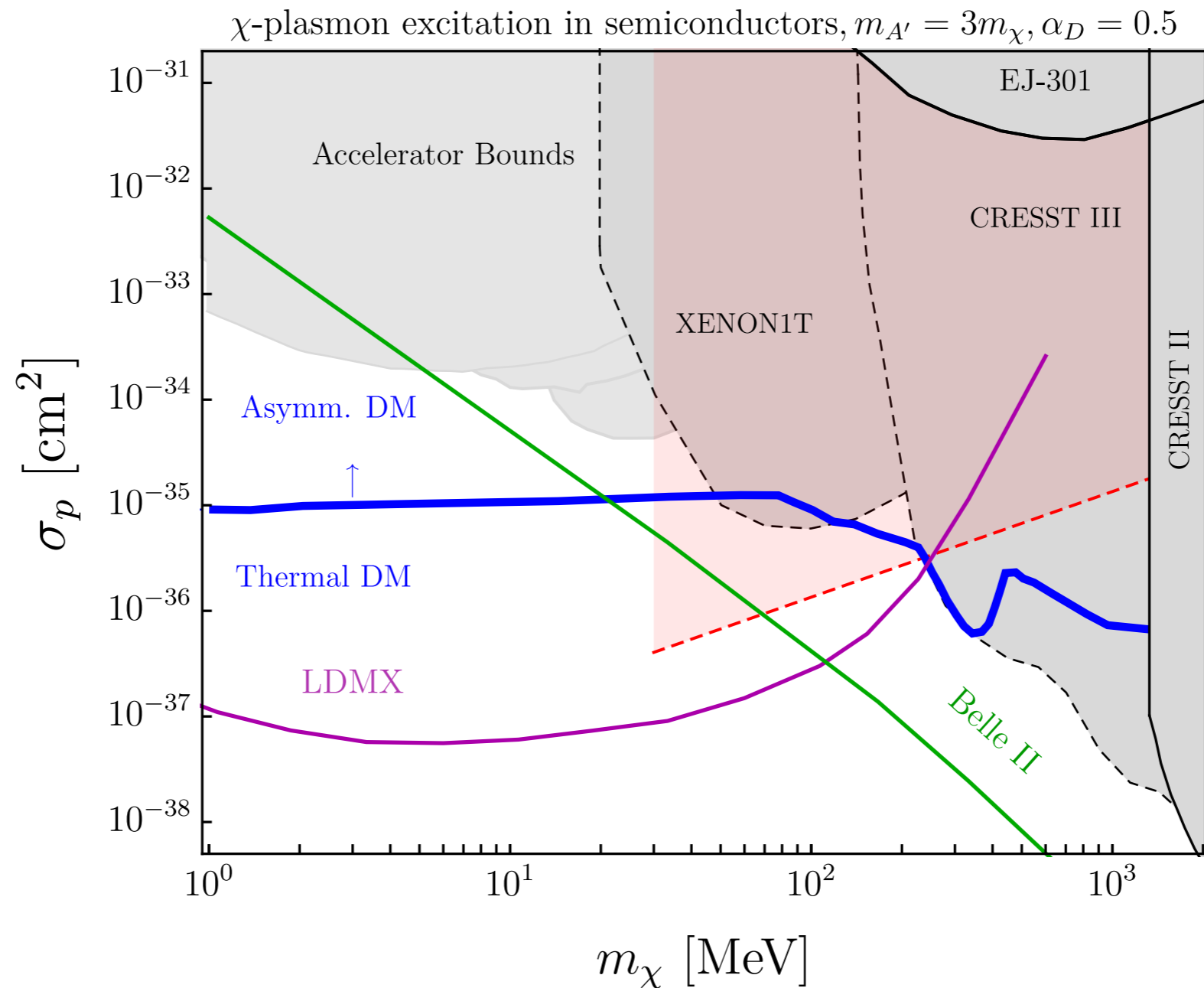
Naive limits for equal electron/proton couplings
Translated from DM-e scattering limits

Secondary Plasmon Excitation Model



Naive limits don't apply
Red = favored region

Secondary Plasmon Excitation Model



$$\mathcal{L} \supset -\frac{m_{A'}^2}{2} A'_\mu A'^\mu + A'_\mu (\kappa e J_{\text{EM}}^\mu + g_D J_D^\mu);$$

Dark photon mediator
Contact interaction

Predictions

- 1) Future results should continue to see \sim Hz/kg excesses**
Despite improved shielding + BG rejection
- 2) Annual modulation (but weird!)**
Large rates, should already be possible
No shift in signal shape, **only normalization**
Anisotropic crystals (daily modulation?)
- 3) Other materials should see this**
Xenon crystal should see increased rate over liquid Xe, etc.
- 4) Neutron Scattering in Ge should see plasmon**
Measures secondary excitation probability

Conclusion

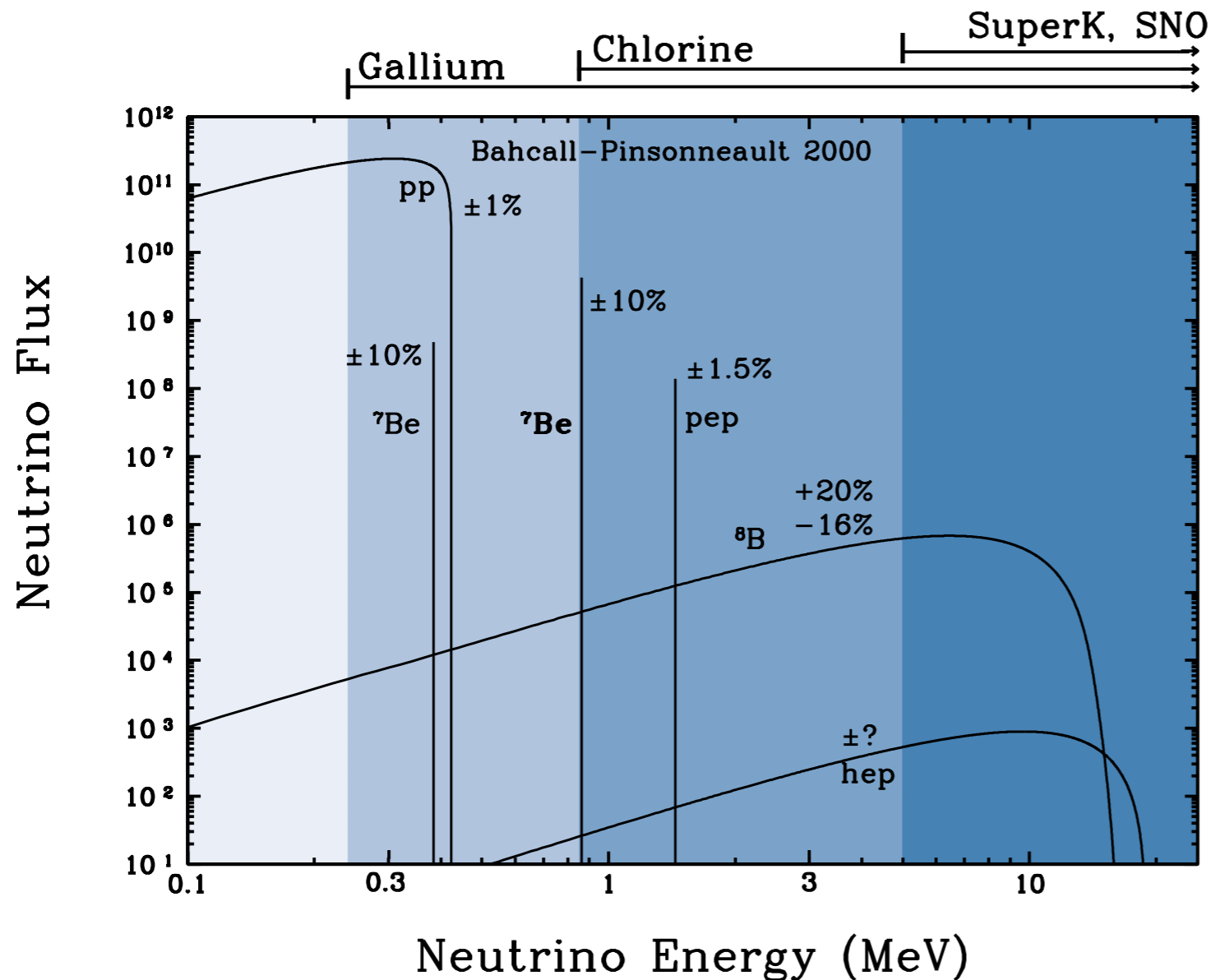
- 1) There are many sub-GeV direct-detection excesses**
- 2) There is a candidate process to explain these results**
- 3) Currently no known plausible SM explanation**
- 4) This process may originate from DM interactions**
 - direct plasmon excitation (fast millicharge DM fraction)
 - secondary plasmon excitation (normal DM setup)

Thanks!

Backup

Solar pp Neutrinos?

Most abundant terrestrial neutrino flux



Can't make plasmon

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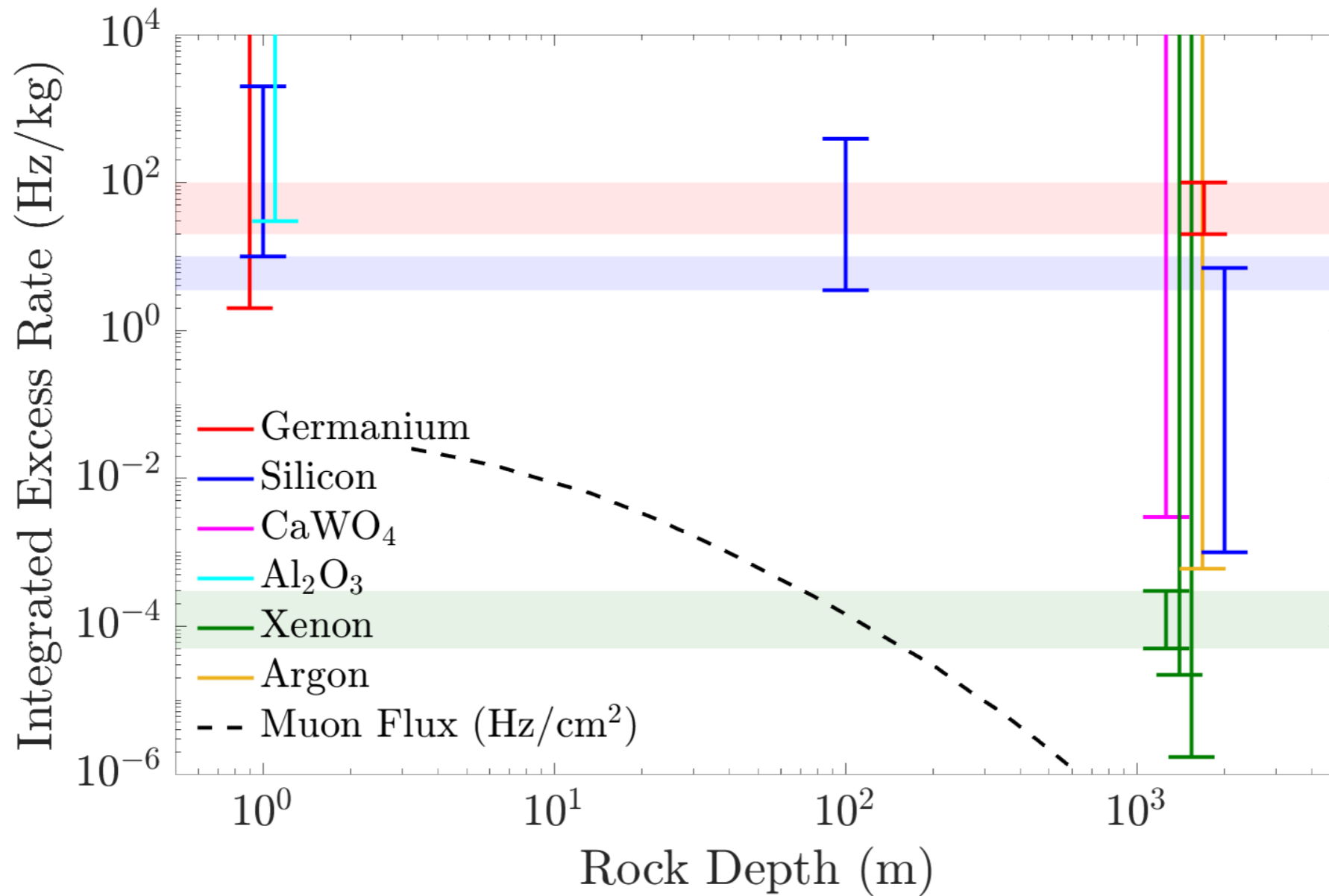
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Possible in principle

Neutron could scatter nucleus, excite secondary plasmon

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Collar, Baxter, Kahn, Kavner, GK [in preparation]

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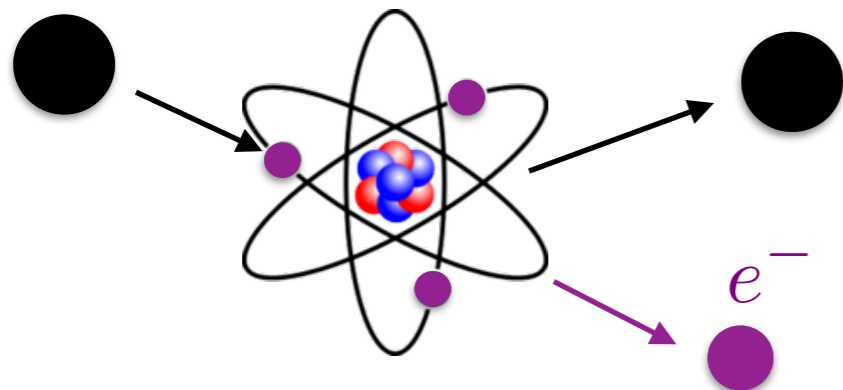
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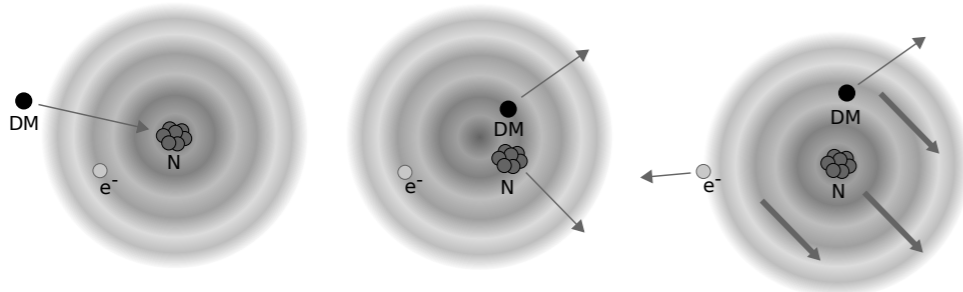
Q: Can the “Migdal effect” realize this?

If you hit the electron directly:



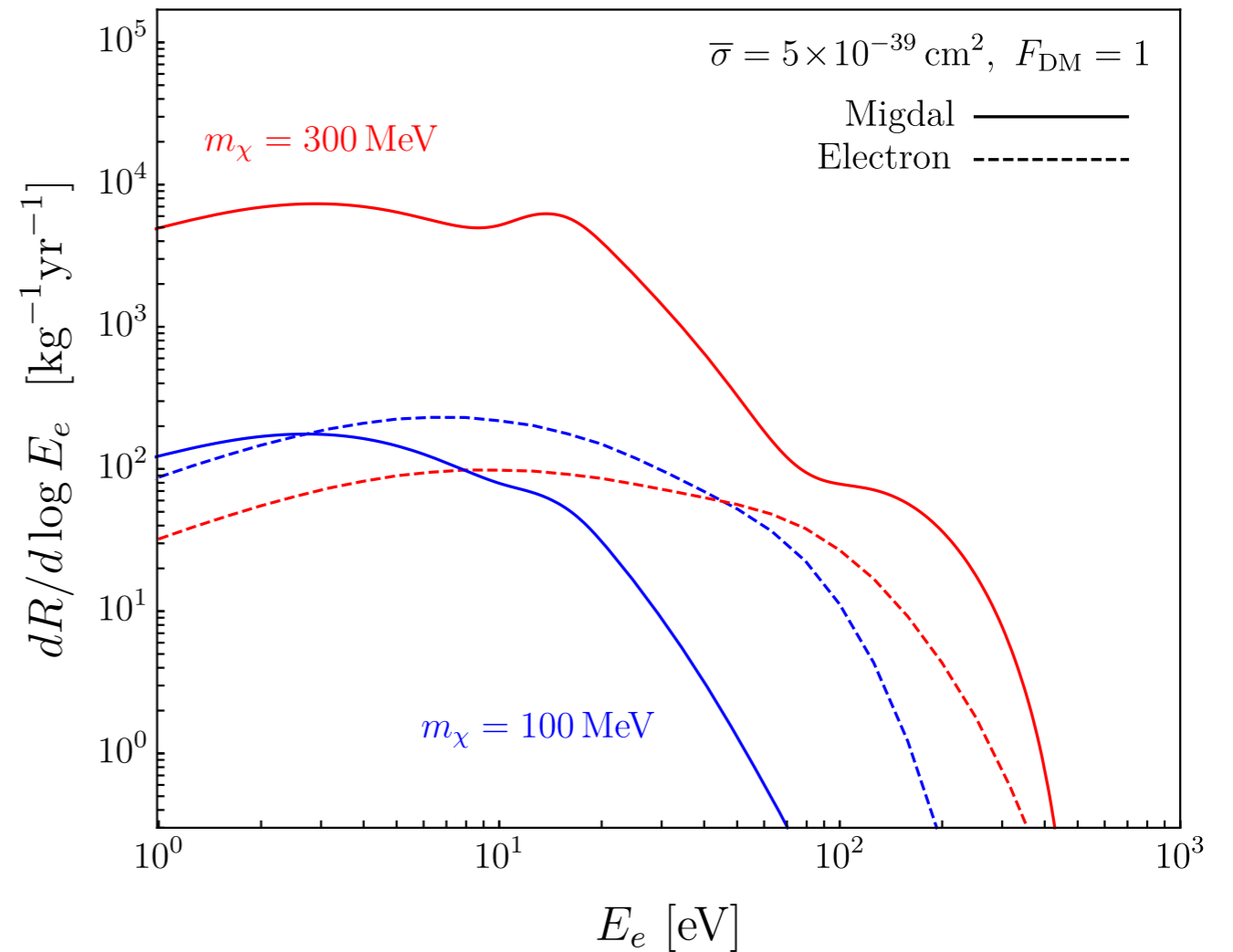
“electron recoil”

If you hit the nucleus:



“Migdal effect”

Migdal Scattering vs. Electron Scattering, Xenon



Same inelastic kinematics, vastly different dynamics!

Q: Can the “Migdal effect” realize this?

A: PROBABLY NOT

Migdal rates from Ibe et. al. too low, however:

Calculations assume single-atom systems

Also assume Hydrogenic wave functions

No treatment of multi-body physics (phonons etc)

See recent progress: Essig, Pradler, Sholapurkar, Yu 1908.10881